

TLE214x, TLE214xA
EXCALIBUR LOW-NOISE HIGH-SPEED
PRECISION OPERATIONAL AMPLIFIERS

SLOS183D – FEBRUARY 1997 – REVISED OCTOBER 2012

- **Low Noise**
10 Hz . . . 15 nV/ $\sqrt{\text{Hz}}$
1 kHz . . . 10.5 nV/ $\sqrt{\text{Hz}}$
- **10000-pF Load Capability**
- **20-mA Min Short-Circuit Output Current**
- **27-V/ μs Min Slew Rate**
- **High Gain-Bandwidth Product . . . 5.9 MHz**
- **Low V_{IO} . . . 500 μV Max at 25°C**
- **Single or Split Supply . . . 4 V to 44 V**
- **Fast Settling Time**
340 ns to 0.1%
400 ns to 0.01%
- **Saturation Recovery . . . 150 ns**
- **Large Output Swing**
 $V_{\text{CC-}} + 0.1 \text{ V}$ to $V_{\text{CC+}} - 1 \text{ V}$

description

The TLE214x and TLE214xA devices are high-performance, internally compensated operational amplifiers built using Texas Instruments complementary bipolar Excalibur process. The TLE214xA is a tighter offset voltage grade of the TLE214x. Both are pin-compatible upgrades to standard industry products.

The design incorporates an input stage that simultaneously achieves low audio-band noise of 10.5 nV/ $\sqrt{\text{Hz}}$ with a 10-Hz 1/f corner and symmetrical 40-V/ μs slew rate typically with loads up to 800 pF. The resulting low distortion and high power bandwidth are important in high-fidelity audio applications. A fast settling time of 340 ns to 0.1% of a 10-V step with a 2-k Ω /100-pF load is useful in fast actuator/positioning drivers. Under similar test conditions, settling time to 0.01% is 400 ns.

The devices are stable with capacitive loads up to 10 nF, although the 6-MHz bandwidth decreases to 1.8 MHz at this high loading level. As such, the TLE214x and TLE214xA are useful for low-droop sample-and-holds and direct buffering of long cables, including 4-mA to 20-mA current loops.

The special design also exhibits an improved insensitivity to inherent integrated circuit component mismatches as is evidenced by a 500- μV maximum offset voltage and 1.7- $\mu\text{V}/^{\circ}\text{C}$ typical drift. Minimum common-mode rejection ratio and supply-voltage rejection ratio are 85 dB and 90 dB, respectively.

Device performance is relatively independent of supply voltage over the $\pm 2\text{-V}$ to $\pm 22\text{-V}$ range. Inputs can operate between $V_{\text{CC-}} - 0.3$ to $V_{\text{CC+}} - 1.8 \text{ V}$ without inducing phase reversal, although excessive input current may flow out of each input exceeding the lower common-mode input range. The all-npn output stage provides a nearly rail-to-rail output swing of $V_{\text{CC-}} - 0.1$ to $V_{\text{CC+}} - 1 \text{ V}$ under light current-loading conditions. The device can sustain shorts to either supply since output current is internally limited, but care must be taken to ensure that maximum package power dissipation is not exceeded.

Both versions can also be used as comparators. Differential inputs of $V_{\text{CC}\pm}$ can be maintained without damage to the device. Open-loop propagation delay with TTL supply levels is typically 200 ns. This gives a good indication as to output stage saturation recovery when the device is driven beyond the limits of recommended output swing.

Both the TLE214x and TLE214xA are available in a wide variety of packages, including both the industry-standard 8-pin small-outline version and chip form for high-density system applications. The C-suffix devices are characterized for operation from 0°C to 70°C, I-suffix devices from -40°C to 105°C, and M-suffix devices over the full military temperature range of -55°C to 125°C.



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 **TEXAS
INSTRUMENTS**

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TLE2141 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES		
		SMALL OUT- LINE† (D)	CERAMIC DIP (JG)	PLASTIC DIP (P)
0°C to 70°C	500 µV 900 µV	TLE2141ACD TLE2141CD	—	TLE2141ACP TLE2141CP
–40°C to 105°C	500 µV 900 µV	TLE2141AID TLE2141ID	—	TLE2141AIP TLE2141IP
–55°C to 125°C	500 µV 900 µV	— TLE2141MD	TLE2141AMJG TLE2141MJG	— —

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLE2141ACDR).

TLE2142 AVAILABLE OPTIONS

PACKAGED DEVICES							
T _A	V _{IO} max AT 25°C	SMALL OUTLINE† (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	TSSOP‡ (PW)	CERAMIC FLAT PACK (U)
0°C to 70°C	750 µV	TLE2142ACD	—	—	TLE2142ACP	—	—
	1200 µV	TLE2142CD	—	—	TLE2142CP	TLE2142CPWLE	—
–40°C to 105°C	750 µV	TLE2142AID	—	—	TLC2142AIP	—	—
	1200 µV	TLE2142ID	—	—	TLC2142IP	—	—
–55°C to 125°C	750 µV	TLE2142AMD	TLE2142AMFK	TLE2142AMJG	—	—	TLE2142AMU
	1200 µV	TLE2142MD	TLE2142MFK	TLE2142MJG	—	—	TLE2142MU

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLC2142ACDR).

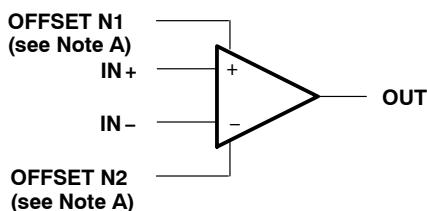
‡ The PW packages are available left-ended taped and reeled. Add LE the suffix to device type (e.g., TLC2142CPWLE).

TLE2144 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES			
		SMALL OUTLINE† (DW)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)
0°C to 70°C	1.5 mV	—	—	—	TLE2144ACN
	2.4 mV	TLE2144CDW	—	—	TLE2144CN
–40°C to 105°C	1.5 mV	—	—	—	TLE2144AIN
	2.4 mV	TLE2144IDW	—	—	TLE2144IN
–55°C to 125°C	1.5 mV	—	TLE2144AMFK	TLE2144AMJ	—
	2.5 mV	TLE2144MDW	TLE2144MFK	TLE2144MJ	—

† The DW packages are available taped and reeled. Add R suffix to device type (e.g., TLE2144CDWR).

symbol



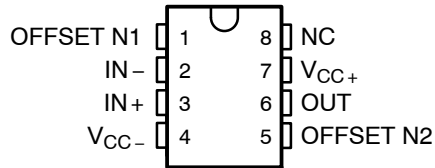
NOTES: A. OFFSET N1 AND OFFSET N2 are only available on the TLE2241x devices.

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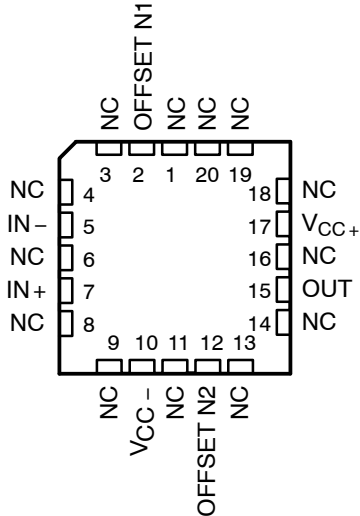
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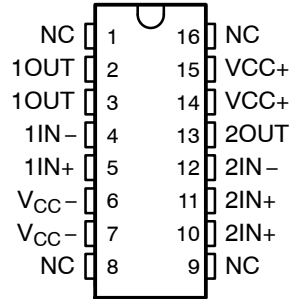
TLE2141
D, JG, OR P PACKAGE
(TOP VIEW)



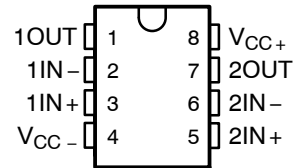
TLE2141
FK PACKAGE
(TOP VIEW)



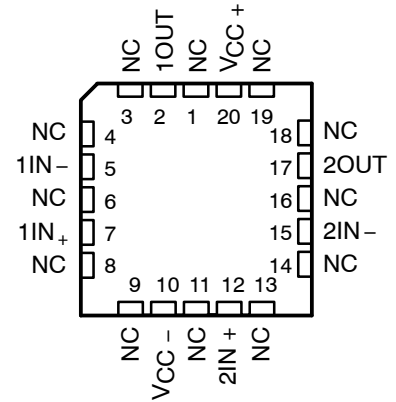
TLE2142
PW PACKAGE
(TOP VIEW)



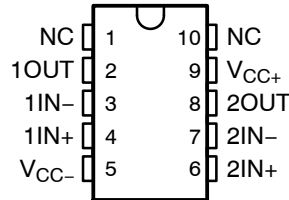
TLE2142
D, JG, OR P PACKAGE
(TOP VIEW)



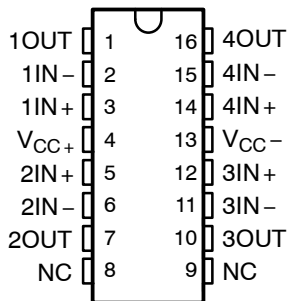
TLE2142
FK PACKAGE
(TOP VIEW)



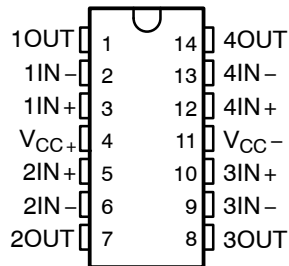
TLE2142
U PACKAGE
(TOP VIEW)



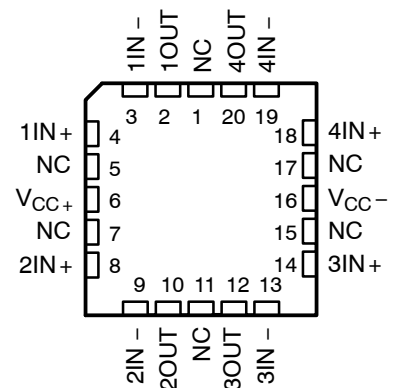
TLE2144
DW PACKAGE
(TOP VIEW)



TLE2144
J OR N PACKAGE
(TOP VIEW)

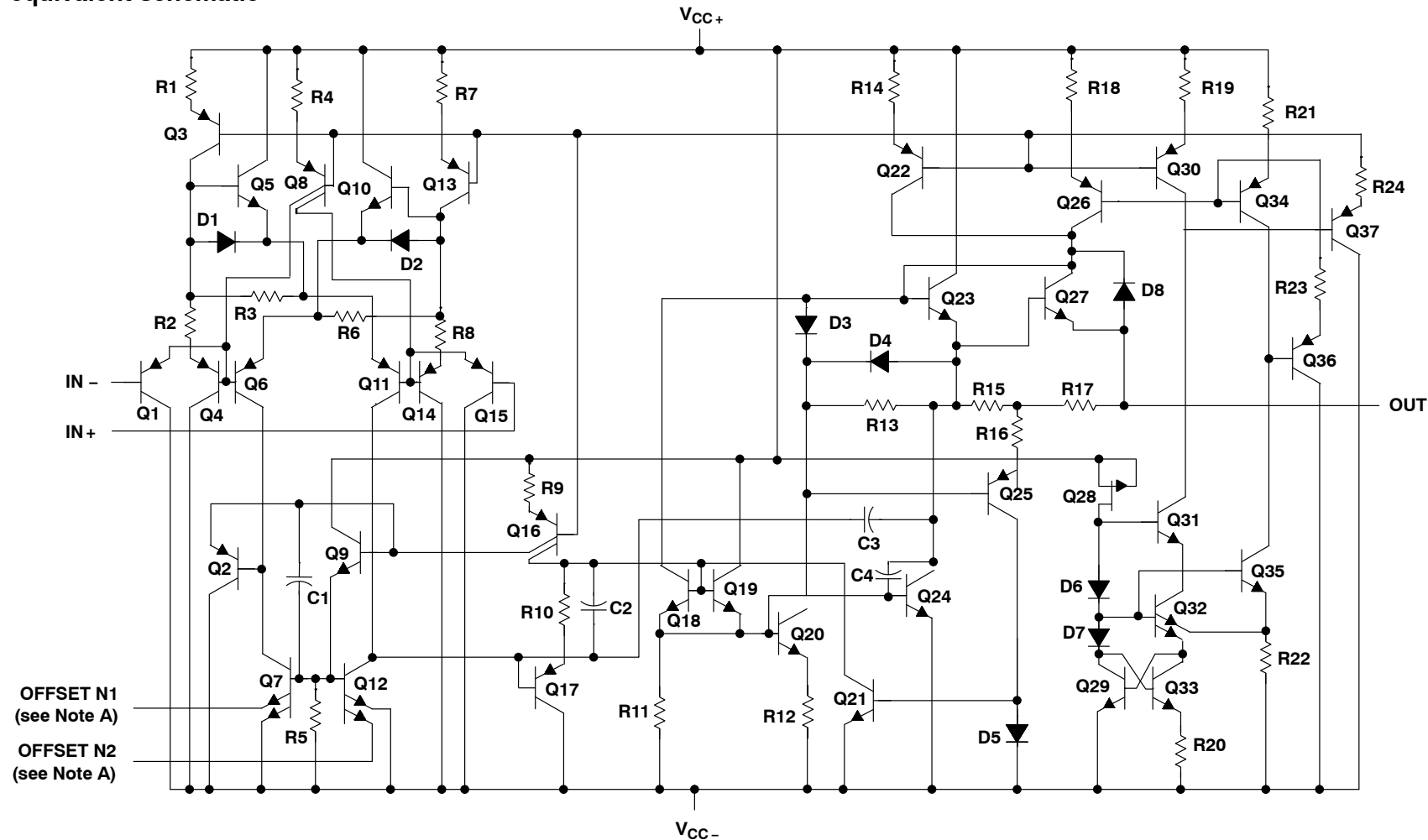


TLE2144
FK PACKAGE
(TOP VIEW)



NC – No internal connection

equivalent schematic



NOTE A: OFFSET N1 AND OFFSET N2 are only available on the TLE2141x devices.

ACTUAL DEVICE COMPONENT COUNT			
COMPONENT	TLE2141	TLE2142	TLE2144
Transistors	46	65	130
Resistors	24	43	86
Diodes	8	14	28
Capacitors	4	8	16
Epi-FET	1	1	2

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TLE2141C electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2141C			TLE2141AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$ $V_{IC} = 2.5\text{ V}$ $R_S = 50\ \Omega$	25°C	225	1400		200	1000		μV
		Full range		1700			1300		
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range		150			150		
I_{IB} Input bias current		25°C	–0.8	–2		–0.8	–2		μA
		Full range		–2.1			–2.1		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	–0.3 to 3.2		0 to 3	–0.3 to 3.2		V
		Full range	0 to 2.9			0 to 2.9			
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
		Full range	3.8			3.8			
	$I_{OH} = -1.5\text{ mA}$	25°C	3.8	4		3.8	4		
		Full range	3.7			3.7			
	$I_{OH} = -15\text{ mA}$	25°C	3.2	3.7		3.2	3.7		
		Full range	3.2			3.2			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C		75	125		75	125	mV
		Full range			150			150	
	$I_{OL} = 1.5\text{ mA}$	25°C		150	225		150	225	
		Full range			250			250	
	$I_{OL} = 15\text{ mA}$	25°C		1.2	1.6		1.2	1.6	V
		Full range			1.7			1.7	
A_{VD} Large-signal differential voltage amplification	$V_{CC} = \pm 2.5\text{ V}$, $R_L = 2\text{ k}\Omega$, $V_O = 1\text{ V}$ to -1.5 V	25°C	50	220		50	220		V/mV
		Full range	25			25			
r_i Input resistance		25°C		70			70		$\text{M}\Omega$
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V}$ to $\pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, No load, $V_{IC} = 2.5\text{ V}$	25°C		3.4	4.4		3.4	4.4	mA
		Full range			4.6			4.6	

[†] Full range is 0°C to 70°C.

TLE2141C operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141C			TLE2141AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}^\dagger$, $R_L = 2\text{ k}\Omega$, †		45			45			V/ μ s
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μ s
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$	15			15			nV/ $\sqrt{\text{Hz}}$	
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$	10.5			10.5				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μ V
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$, $R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$	$C_L = 100\text{ pF}^\dagger$	5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}^\dagger$	5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}^\dagger$		660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$	$C_L = 100\text{ pF}^\dagger$	57°			57°			

† R_L and C_L terminated to 2.5 V.

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TLE2141C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2141C			TLE2141AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$ $R_S = 50\ \Omega$	25°C		200	900		175	500	μV
		Full range			1300			800	
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu V/^\circ C$
I_{IO} Input offset current		25°C		7	100		7	100	nA
		Full range			150			150	
I_{IB} Input bias current		25°C		-0.7	-1.5		-0.7	-1.5	μA
		Full range			-1.6			-1.6	
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	-15 to 13	-15.3 to 13.2		-15 to 13	-15.3 to 13.2		V
		Full range	-15 to 12.9	-15.3 to 13.1		-15 to 12.9	-15.3 to 13.1		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150\ \mu A$	25°C		13.8	14.1		13.8	14.1	V
		Full range			13.7			13.7	
	$I_O = -1.5\ mA$	25°C		13.7	14		13.7	14	
		Full range			13.6			13.6	
	$I_O = -15\ mA$	25°C		13.1	13.7		13.1	13.7	
		Full range			13			13	
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150\ \mu A$	25°C		-14.7	-14.9		-14.7	-14.9	V
		Full range			-14.6			-14.6	
	$I_O = 1.5\ mA$	25°C		-14.5	-14.8		-14.5	-14.8	
		Full range			-14.4			-14.4	
	$I_O = 15\ mA$	25°C		-13.4	-13.8		-13.4	-13.8	
		Full range			-13.3			-13.3	
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\ V$	25°C		100	450		100	450	V/mV
		Full range			75			75	
r_i Input resistance	$R_L = 2\ k\Omega$	25°C		65			65		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\ MHz$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C		85	108		85	108	dB
		Full range			80			80	
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\ V$ to $\pm 15\ V$, $R_S = 50\ \Omega$	25°C		90	106		90	106	dB
		Full range			85			85	
I_{OS} Short-circuit output current	$V_O = 0$	25°C		$V_{ID} = 1\ V$	-25	-50		$V_{ID} = -1\ V$	mA
				$V_{ID} = -1\ V$	20	31		$V_{ID} = -1\ V$	
I_{CC} Supply current	$V_O = 0$, No load	25°C		3.5	4.5		3.5	4.5	mA
		Full range			4.7			4.7	

[†] Full range is 0°C to 70°C.



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TLE2141C operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141C			TLE2141AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$	$R_L = 2\text{ k}\Omega$	27	45		27	45		V/ μs
SR–	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%		0.34			0.34		μs
			To 0.01%		0.4			0.4		
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$	$f = 10\text{ Hz}$		15			15		nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$	$f = 1\text{ kHz}$		10.5			10.5		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$			0.48			0.48		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			0.51			0.51		
I_n	Equivalent input noise current	$f = 10\text{ Hz}$			1.89			1.89		pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$			0.47			0.47		
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$	$R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$		0.01%			0.01%		
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$	$C_L = 100\text{ pF}$		6			6		MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$		5.9			5.9		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$		668			668		kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$	$C_L = 100\text{ pF}$		58°			58°		

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TLE2142C electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142C			TLE2142AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$, $R_S = 50\ \Omega$, $V_{IC} = 2.5\text{ V}$	25°C	220	1900		200	1500		μV
		Full range		2200			1800		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range		150			150		
I_{IB} Input bias current		25°C	-0.8	-2		-0.8	-2		μA
		Full range		-2.1			-2.1		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	-0.3 to 3.2		0 to 3	-0.3 to 3.2		V
		Full range	0 to 2.9			0 to 2.9			
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
		Full range	3.8			3.8			
	$I_{OH} = -1.5\text{ mA}$	25°C	3.8	4		3.8	4		
		Full range	3.7			3.7			
	$I_{OH} = -15\text{ mA}$	25°C	3.4	3.7		3.4	3.7		
		Full range	3.4			3.4			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C		75	125		75	125	mV
		Full range			150			150	
	$I_{OL} = 1.5\text{ mA}$	25°C		150	225		150	225	
		Full range			250			250	
	$I_{OL} = 15\text{ mA}$	25°C		1.2	1.4		1.2	1.4	V
		Full range			1.5			1.5	
A_{VD} Large-signal differential voltage amplification	$V_{CC} = \pm 2.5\text{ V}$, $R_L = 2\text{ k}\Omega$, $V_O = 1\text{ V to } -1.5\text{ V}$	25°C	50	220		50	220		V/mV
		Full range	25			25			
r_i Input resistance		25°C		70			70		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, No load, $V_{IC} = 2.5\text{ V}$	25°C		6.6	8.8		6.6	8.8	mA
		Full range			9.2			9.2	

† Full range is 0°C to 70°C.

TLE2142C operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142C			TLE2142AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$ $R_L = 2\text{ k}\Omega^\dagger$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$	15			15			nV/ $\sqrt{\text{Hz}}$	
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$	10.5			10.5				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$, $R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	5.9			5.9			MHz	
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$, $f = 100\text{ kHz}$	5.8			5.8			MHz	
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	660			660			kHz	
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	57°			57°				

[†] R_L terminates at 2.5 V.

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TLE2142C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142C			TLE2142AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega$	25°C	290	1200		275	750		μV
		Full range		1600			1200		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		150			150		
I_{IB} Input bias current		25°C	-0.7	-1.5		-0.7	-1.5		μA
		Full range		-1.6			-1.6		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	-15 to 13	-15.3 to 13.2		-15 to 13	-15.3 to 13.2		V
		Full range	-15 to 12.9	-15.3 to 13.1		-15 to 12.9	-15.3 to 13.1		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
		Full range	13.7			13.7			
	$I_O = -1.5$ mA	25°C	13.7	14		13.7	14		
		Full range	13.6			13.6			
	$I_O = -15$ mA	25°C	13.3	13.7		13.3	13.7		
		Full range	13.2			13.2			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	-14.7	-14.9		-14.7	-14.9		V
		Full range	-14.6			-14.6			
	$I_O = 1.5$ mA	25°C	-14.5	-14.8		-14.5	-14.8		
		Full range	-14.4			-14.4			
	$I_O = 15$ mA	25°C	-13.4	-13.8		-13.4	-13.8		
		Full range	-13.3			-13.3			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V	25°C	100	450		100	450		V/mV
		Full range	75			75			
r_i Input resistance	$R_L = 2$ k Ω	25°C		65			65		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50 \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	-25	-50		-25	-50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0, \text{ No load}$	25°C	6.9	9		6.9	9		mA
		Full range		9.4			9.4		

† Full range is 0°C to 70°C.



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TLE2142C operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142C			TLE2142AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$	$R_L = 2\text{ k}\Omega$	27	45		27	45		$\text{V}/\mu\text{s}$
SR–	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%		0.34			0.34		μs
			To 0.01%		0.4			0.4		
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$			15			15		$\text{nV}/\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$			10.5			10.5		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$			0.48			0.48		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			0.51			0.51		
I_n	Equivalent input noise current	$f = 10\text{ Hz}$			1.89			1.89		$\text{pA}/\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$			0.47			0.47		
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = 10$, $f = 10\text{ kHz}$			0.01%			0.01%		
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$			6			6		MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$		5.9			5.9		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = 1$, $C_L = 100\text{ pF}$			668			668		kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$			58°			58°		

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TLE2144C electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T _A [†]	TLE2144C			TLE2144AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _O = 2.5 V, V _{IC} = 2.5 V R _S = 50 Ω,	25°C	0.5 3.8		0.5 3		mV		
			Full range	4.4		3.6				
α _{VIO}	Temperature coefficient of input offset voltage		Full range	1.7		1.7		μV/°C		
I _{IO}	Input offset current		25°C	8 100		8 100		nA		
			Full range	150		150				
I _{IB}	Input bias current		25°C	–0.8 –2		–0.8 –2		μA		
		Full range	–2.1		–2.1					
V _{ICR}	Common-mode input voltage range	R _S = 50 Ω	25°C	0 to 3	–0.3 to 3.2	0 to 3	–0.3 to 3.2	V		
			Full range	0 to 2.9		0 to 2.9				
V _{OH}	High-level output voltage	I _{OH} = –150 μA	25°C	3.9	4.1	3.9	4.1	V		
			Full range	3.8		3.8				
		I _{OH} = –1.5 mA	25°C	3.8	4	3.8	4			
			Full range	3.7		3.7				
		I _{OH} = –15 mA	25°C	3.4	3.7	3.4	3.7			
			Full range	3.4		3.4				
V _{OL}	Low-level output voltage	I _{OL} = 150 μA	25°C	75 125		75 125		mV		
			Full range	150		150				
		I _{OL} = 1.5 mA	25°C	150 225		150 225				
			Full range	250		250				
		I _{OL} = 15 mA	25°C	1.2 1.6		1.2 1.6		V		
			Full range	1.7		1.7				
A _{VD}	Large-signal differential voltage amplification	V _{CC} = ±2.5 V, R _L = 2 kΩ, V _O = 1 V to –1.5 V	25°C	50	95	50	95	V/mV		
			Full range	25		25				
r _i	Input resistance		25°C	70		70		MΩ		
c _i	Input capacitance		25°C	2.5		2.5		pF		
z _o	Open-loop output impedance	f = 1 MHz	25°C	30		30		Ω		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin} , R _S = 50 Ω	25°C	85	118	85	118	dB		
			Full range	80		80				
k _{SVR}	Supply-voltage rejection ratio (ΔV _{CC±} /ΔV _{IO})	V _{CC±} = ±2.5 V to ±15 V, R _S = 50 Ω	25°C	90	106	90	106	dB		
			Full range	85		85				
I _{CC}	Supply current	V _O = 2.5 V, No load, V _{IC} = 2.5 V	25°C	13.2 17.6		13.2 17.6		mA		
			Full range	18.5		18.5				

† Full range is 0°C to 70°C.

TLE2144C operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144C			TLE2144AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 500\text{ pF}$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$	15			15			nV/ $\sqrt{\text{Hz}}$	
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$	10.5			10.5				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$,	$R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$	0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}$	5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $f = 100\text{ kHz}$		5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}$	57°			57°			

[†] R_L terminates at 2.5 V

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TLE2144C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2144C			TLE2144AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _{IC} = 0, V _O = 0 R _S = 50 Ω,		25°C	0.6		2.4	0.5		1.5	mV
	Full range			3.2		2.4					
α _{VIO}	Temperature coefficient of input offset voltage			Full range	1.7		1.7		μV/°C		
I _{IO}	Input offset current			25°C	7		100	7		100	nA
				Full range	150		150				
I _{IB}	Input bias current			25°C	−0.7		−1.5	−0.7		−1.5	μA
		Full range	−1.6		−1.6						
V _{ICR}	Common-mode input voltage range	R _S = 50 Ω		25°C	−15 to 13	−15.3 to 13.2	−15 to 13		−15.3 to 13.2	V	
				Full range	−15 to 12.9	−15.3 to 13.1	−15 to 12.9		−15.3 to 13.1		
V _{OM+}	Maximum positive peak output voltage swing	I _O = −150 μA		25°C	13.8	14.1	13.8		14.1	V	
				Full range	13.7		13.7				
		I _O = −1.5 mA		25°C	13.7	14	13.7		14		
				Full range	13.6		13.6				
		I _O = −15 mA		25°C	13.1	13.7	13.1		13.7		
				Full range	13		13				
V _{OM−}	Maximum negative peak output voltage swing	I _O = 150 μA		25°C	−14.7	−14.9	−14.7		−14.9	V	
				Full range	−14.6		−14.6				
		I _O = 1.5 mA		25°C	−14.5	−14.8	−14.5		−14.8		
				Full range	−14.4		−14.4				
		I _O = 15 mA		25°C	−13.4	−13.8	−13.4		−13.8		
				Full range	−13.3		−13.3				
A _{VD}	Large-signal differential voltage amplification	V _O = ±10 V		25°C	100	170	100		170	V/mV	
				Full range	75		75				
r _i	Input resistance	R _L = 2 kΩ		25°C	65		65		MΩ		
c _i	Input capacitance			25°C	2.5		2.5		pF		
z _o	Open-loop output impedance	f = 1 MHz		25°C	30		30		Ω		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin} , R _S = 50 Ω		25°C	85	108	85		108	dB	
				Full range	80		80				
k _{SVR}	Supply-voltage rejection ratio (ΔV _{CC±} /ΔV _{IO})	V _{CC±} = ±2.5 V to ±15 V, R _S = 50 Ω		25°C	90	106	90		106	dB	
				Full range	85		85				
I _{OS}	Short-circuit output current	V _O = 0	V _{ID} = 1 V V _{ID} = −1 V	25°C	−25	−50	−25		−50	mA	
					20	31	20		31		
I _{CC}	Supply current	V _O = 0, No load		25°C	13.8		18	13.8		18	mA
				Full range	18.8		18.8				

† Full range is 0°C to 70°C.

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TLE2144C operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144C			TLE2144AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 500\text{ pF}$		27	45		27	45	V/ μ s	
SR –	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%	0.34			0.34			μ s
			To 0.01%	0.4			0.4			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μ V
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.89			1.89			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.47			0.47			
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$,	$R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$	0.01%			0.01%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$	6			6			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$,	5.9			5.9			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	668			668			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$	58°			58°			

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TLE2141I electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2141I			TLE2141AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}, R_S = 50\ \Omega, V_{IC} = 2.5\text{ V}$	25°C	225	1400		200	1000		μV
		Full range			1900			1500	
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range			200			200	
I_{IB} Input bias current		25°C	-0.8	-2		-0.8	-2		μA
		Full range			-2.2			-2.2	
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	-0.3 to 3.2		0 to 3	-0.3 to 3.2		V
		Full range	0 to 2.7	-0.3 to 2.9		0 to 2.7	-0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.2	3.7		3.2	3.7		
	$I_{OH} = -100\ \mu\text{A}$	Full range	3.8			3.8			
	$I_{OH} = -1\text{ mA}$		3.7			3.7			
	$I_{OH} = -10\text{ mA}$		3.3			3.3			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\ \mu\text{A}$		150	225		150	225		
	$I_{OL} = 15\text{ mA}$		1.2	1.6		1.2	1.6		V
	$I_{OL} = 100\ \mu\text{A}$	Full range	175			175			mV
	$I_{OL} = 1\text{ mA}$		225			225			
	$I_{OL} = 10\text{ mA}$		1.4			1.4			V
A_{VD} Large-signal differential voltage amplification	$V_{CC} = \pm 2.5\text{ V}, R_L = 2\text{ k}\Omega, V_O = 1\text{ V to } -1.5\text{ V}$	25°C	50	220		50	220		V/mV
		Full range	10			10			
r_i Input resistance		25°C	70			70			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}, R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}, V_{IC} = 2.5\text{ V}, \text{ No load,}$	25°C	3.4	4.4		3.4	4.4		mA
		Full range			4.6			4.6	

† Full range is -40°C to 105°C .



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TLE2141I operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141I			TLE2141AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1,$ $C_L = 500\text{ pF}$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1,$ 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega,$ $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega,$ $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V},$ $R_L = 2\text{ k}\Omega^\dagger,$ $A_{VD} = 2,$ $f = 10\text{ kHz}$		0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger,$ $C_L = 100\text{ pF}^\ddagger$		5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$ $C_L = 100\text{ pF}^\ddagger,$ $f = 100\text{ kHz}$		5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V},$ $R_L = 2\text{ k}\Omega^\dagger,$ $A_{VD} = 1,$ $C_L = 100\text{ pF}^\ddagger$		660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger,$ $C_L = 100\text{ pF}^\ddagger$		57°			57°			

[†] R_L and C_L terminated to 2.5 V.

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TLE2141I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2141I			TLE2141AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50 \Omega, V_O = 0$	25°C	200	900		175	500		μV
		Full range		1500			1000		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		200			200		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.7			–1.7		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.7	–15.3 to 12.9		–15 to 12.7	–15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5$ mA		13.7	14		13.7	14		
	$I_O = -15$ mA		13.1	13.7		13.1	13.7		
	$I_O = -100 \mu A$	Full range	13.7			13.7			
	$I_O = -1$ mA		13.6			13.6			
	$I_O = -10$ mA		13.1			13.1			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
	$I_O = 1.5$ mA		–14.5	–14.8		–14.5	–14.8		
	$I_O = 15$ mA		–13.4	–13.8		–13.4	–13.8		
	$I_O = 100 \mu A$	Full range	–14.6			–14.6			
	$I_O = 1$ mA		–14.5			–14.5			
	$I_O = 10$ mA		–13.4			–13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 2$ k Ω	25°C	100	450		100	450		V/mV
		Full range	40			40			
r_i Input resistance		25°C	65			65			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50 \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	–25	–50		–25	–50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0, \text{ No load}$	25°C	3.5	4.5		3.5	4.5		mA
		Full range		4.7			4.7		

† Full range is $-40^\circ C$ to $105^\circ C$.



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TLE2141I operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141I			TLE2141AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$	$R_L = 2\text{ k}\Omega$,	27	45		27	45		V/ μs
SR–	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%		0.34			0.34		μs
			To 0.01%		0.4			0.4		
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$,	$f = 10\text{ Hz}$		15			15		nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$,	$f = 1\text{ kHz}$		10.5			10.5		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$			0.48			0.48		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			0.51			0.51		
I_n	Equivalent input noise current	$f = 10\text{ Hz}$			1.89			1.89		pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$			0.47			0.47		
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$,	$R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$		0.01%			0.01%		
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$		6			6		MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$,		5.9			5.9		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$		668			668		kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$		58°			58°		

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TLE2142I electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142I			TLE2142AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ $R_S = 50\ \Omega$	25°C	220	1900		220	1500		μV
		Full range		2400			2000		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range		200			200		
I_{IB} Input bias current		25°C	-0.8	-2		-0.8	-2		μA
		Full range		-2.2			-2.2		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	-0.3 to 3.2		0 to 3	-0.3 to 3.2		V
		Full range	0 to 2.7	-0.3 to 2.9		0 to 2.7	-0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.4	3.7		3.4	3.7		
	$I_{OH} = 100\ \mu\text{A}$	Full range	3.8			3.8			
	$I_{OH} = 1\text{ mA}$		3.7			3.7			
	$I_{OH} = 10\text{ mA}$		3.5			3.5			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\text{ mA}$		150	225		150	225		
	$I_{OL} = 15\text{ mA}$		1.2	1.4		1.2	1.4		V
	$I_{OL} = 100\ \mu\text{A}$	Full range	175			175			mV
	$I_{OL} = 1\text{ mA}$		225			225			
	$I_{OL} = 10\text{ mA}$		1.2			1.2			V
A_{VD} Large-signal differential voltage amplification	$V_{IC} = \pm 2.5\text{ V}$, $V_O = 1\text{ V to } -1.5\text{ V}$ $R_L = 2\text{ k}\Omega$	25°C	50	220		50	220		V/mV
		Full range	10			10			
r_i Input resistance		25°C	70			70			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ No load,	25°C	6.6	8.8		6.6	8.8		mA
		Full range		9.2			9.2		

† Full range is -40°C to 105°C.

TLE2142I operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142I			TLE2142AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$	$R_L = 2\text{ k}\Omega^\dagger$	45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$,	$f = 10\text{ Hz}$	15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$,	$f = 1\text{ kHz}$	10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$,	$R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$	0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}$	5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$,	5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}$	57°			57°			

$^\dagger R_L$ terminates at 2.5 V.

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TLE2142I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142I			TLE2142I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50 \Omega, V_O = 0$	25°C	290	1200		275	750		μV
		Full range		1800			1400		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		200			200		
I_{IB} Input bias current		25°C	-0.7	-1.5		-0.7	-1.5		μA
		Full range		-1.7			-1.7		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	-15 to 13	-15.3 to 13.2		-15 to 13	-15.3 to 13.2		V
		Full range	-15 to 12.7	-15.3 to 12.9		-15 to 12.7	-15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5$ mA		13.7	14		13.7	14		
	$I_O = -15$ mA		13.3	13.7		13.3	13.7		
	$I_O = -100 \mu A$	Full range	13.7			13.7			
	$I_O = -1$ mA		13.6			13.6			
	$I_O = -10$ mA		13.3			13.3			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	-14.7	-14.9		-14.7	-14.9		V
	$I_O = 1.5$ mA		-14.5	-14.8		-14.5	-14.8		
	$I_O = 15$ mA		-13.4	-13.8		-13.4	-13.8		
	$I_O = 100 \mu A$	Full range	-14.6			-14.6			
	$I_O = 1$ mA		-14.5			-14.5			
	$I_O = 10$ mA		-13.4			-13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 2$ k Ω	25°C	100	450		100	450		V/mV
		Full range	40			40			
r_i Input resistance		25°C	65			65			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$	25°C	85	108		85	108		dB
	$R_S = 50 \Omega$	Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	-25	-50		-25	-50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0$, No load	25°C	6.9	9		6.9	9		mA
		Full range		9.4			9.4		

† Full range is -40°C to 105°C.

TLE2142I operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142I			TLE2142AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$	$R_L = 2\text{ k}\Omega$	30	45		30	45		V/ μs
SR–	Negative slew rate			30	42		30	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%		0.34			0.34		μs
			To 0.01%		0.4			0.4		
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$			15			15		nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$			10.5			10.5		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$			0.48			0.48		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			0.51			0.51		
I_n	Equivalent input noise current	$f = 10\text{ Hz}$			1.89			1.89		pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$			0.47			0.47		
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = 10$, $f = 10\text{ kHz}$			0.01%			0.01%		
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$			6			6		MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, $f = 100\text{ kHz}$			5.9			5.9		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = 1$, $C_L = 100\text{ pF}$			668			668		kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$			58°			58°		

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TLE2144I electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2144I			TLE2144AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega, V_O = 0$	25°C	0.5	3.8		0.5	3		mV
		Full range			4.8			4	
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range			200			200	
I_{IB} Input bias current		25°C	–0.8	–2		–0.8	–2		μA
		Full range			–2.2			–2.2	
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	–0.3 to 3.2		0 to 3	–0.3 to 3.2		V
		Full range	0 to 2.7	–0.3 to 2.9		0 to 2.7	–0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.4	3.7		3.4	3.7		
	$I_{OH} = 100\ \mu\text{A}$	Full range	3.8			3.8			
	$I_{OH} = 1\text{ mA}$		3.7			3.7			
	$I_{OH} = 10\text{ mA}$		3.5			3.5			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\ \mu\text{A}$		150	225		150	225		
	$I_{OL} = 15\text{ mA}$		1.2	1.6		1.2	1.6		V
	$I_{OL} = 100\ \mu\text{A}$	Full range		175			175		mV
	$I_{OL} = 1\text{ mA}$			225			225		
	$I_{OL} = 10\text{ mA}$			1.4			1.4		V
A_{VD} Large-signal differential voltage amplification	$V_{IC} = \pm 2.5\text{ V}, R_L = 2\text{ k}\Omega, V_O = 1\text{ V to } -1.5\text{ V}$	25°C	50	95		50	95		V/mV
		Full range	10			10			
r_i Input resistance		25°C		70			70		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}, R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}, V_{IC} = 2.5\text{ V}$ No load,	25°C	13.2	17.6		13.2	17.6		mA
		Full range		18.4			18.4		

† Full range is -40°C to 105°C .



TLE2144I operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144I			TLE2144AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 500\text{ pF}$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$, $R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$		5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$, $f = 100\text{ kHz}$		5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$		660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$		57°			57°			

[†] R_L terminates at 2.5 V

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TLE2144I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2144I			TLE2144AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0,$ $V_O = 0$ $R_S = 50 \Omega$	25°C	0.6	2.4		0.5	1.5		mV
		Full range			3.2			2.8	
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		200			200		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.7			–1.7		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.7	–15.3 to 12.9		–15 to 12.7	–15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5$ mA		13.7	14		13.7	14		
	$I_O = -15$ mA		13.1	13.7		13.1	13.7		
	$I_O = -100 \mu A$	Full range	13.7			13.7			
	$I_O = -1$ mA		13.6			13.6			
	$I_O = -10$ mA		13.1			13.1			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
	$I_O = 1.5$ mA		–14.5	–14.8		–14.5	–14.8		
	$I_O = 15$ mA		–13.4	–13.8		–13.4	–13.8		
	$I_O = 100 \mu A$	Full range	–14.6			–14.6			
	$I_O = 1$ mA		–14.5			–14.5			
	$I_O = 10$ mA		–13.4			–13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 2$ k Ω	25°C	100	170		100	170		V/mV
		Full range	40			40			
r_i Input resistance		25°C	65			65			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $R_S = 50 \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$ $\frac{V_{ID} = 1$ V $V_{ID} = -1$ V	25°C	–25	–50		–25	–50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0,$ No load	25°C	13.8	18		13.8	18		mA
		Full range		18.8			18.8		

† Full range is $-40^\circ C$ to $105^\circ C$.



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TLE2144I operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144I			TLE2144AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 500\text{ pF}$		27	45		27	45	V/ μs	
SR –	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%	0.34			0.34			μs
			To 0.01%	0.4			0.4			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$	15			15			nV/ $\sqrt{\text{Hz}}$	
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$	10.5			10.5				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.89			1.89			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.47			0.47			
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$,	$R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$	0.01%			0.01%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$	6			6			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$,	5.9			5.9			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	668			668			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$	58°			58°			

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TLE2141M electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2141M			TLE2141AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$ $V_{IC} = 2.5\text{ V}$ $R_S = 50\ \Omega$	25°C	225	1400		200	1000		μV
		Full range		2100			1700		
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range		250			250		
I_{IB} Input bias current		25°C	–0.8	–2		–0.8	–2		μA
		Full range		–2.3			–2.3		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	–0.3 to 3.2		0 to 3	–0.3 to 3.2		V
		Full range	0 to 2.7	–0.3 to 2.9		0 to 2.7	–0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.2	3.7		3.2	3.7		
	$I_{OH} = -100\ \mu\text{A}$	Full range	3.75			3.75			
	$I_{OH} = -1\text{ mA}$		3.65			3.65			
	$I_{OH} = -10\text{ mA}$		3.25			3.25			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\ \mu\text{A}$		150	225		150	225		
	$I_{OL} = 15\text{ mA}$		1.2	1.4		1.2	1.4		V
	$I_{OL} = 100\ \mu\text{A}$	Full range	200			200			mV
	$I_{OL} = 1\text{ mA}$		250			225			
	$I_{OL} = 10\text{ mA}$		1.25			1.25			V
A_{VD} Large-signal differential voltage amplification	$V_{IC} = \pm 2.5\text{ V}$, $R_L = 2\text{ k}\Omega$, $V_O = 1\text{ V to } -1.5\text{ V}$	25°C	50	220		50	220		V/mV
		Full range	5			5			
r_i Input resistance		25°C	70			70			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ No load,	25°C	3.4	4.4		3.4	4.4		mA
		Full range		4.6			4.6		

† Full range is -55°C to 125°C .

TLE2141M operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141M			TLE2141AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$,	$R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$	0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}^\dagger$	5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}^\dagger$,	5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$	$R_L = 2\text{ k}\Omega^\dagger$,	660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}^\dagger$	57°			57°			

$^\dagger R_L$ and C_L terminated to 2.5 V.

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PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2141M			TLE2141AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, \quad R_S = 50 \, \Omega$	25°C	200	900		175	500		μV
		Full range		1700			1200		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		250			250		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.8			–1.8		
V_{ICR} Common-mode input voltage range	$R_S = 50 \, \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.7	–15.3 to 12.9		–15 to 12.7	–15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \, \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5 \, mA$		13.7	14		13.7	14		
	$I_O = -15 \, mA$		13.1	13.7		13.1	13.7		
	$I_O = -100 \, \mu A$	Full range	13.7			13.7			
	$I_O = -1 \, mA$		13.6			13.6			
	$I_O = -10 \, mA$		13.1			13.1			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \, \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
	$I_O = 1.5 \, mA$		–14.5	–14.8		–14.5	–14.8		
	$I_O = 15 \, mA$		–13.4	–13.8		–13.4	–13.8		
	$I_O = 100 \, \mu A$	Full range	–14.6			–14.6			
	$I_O = 1 \, mA$		–14.5			–14.5			
	$I_O = 10 \, mA$		–13.4			–13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \, V, \quad R_L = 2 \, k\Omega$	25°C	100	450		100	450		V/mV
		Full range	20			20			
r_i Input resistance		25°C	65			65			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1 \, MHz$	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, \quad R_S = 50 \, \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5 \, V$ to $\pm 15 \, V, \quad R_S = 50 \, \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	–25	–50		–25	–50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0, \quad V_{IC} = 2.5 \, V$	25°C	3.5	4.5		3.5	4.5		mA
		Full range		4.7			4.7		

† Full range is $-55^\circ C$ to $125^\circ C$.



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TLE2141M operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141M			TLE2141AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	A _{VD} = − 1, R _L = 2 kΩ, C _L = 100 pF		27	45		27	45	V/μs	
SR −	Negative slew rate			27	42		27	42		
t _s	Settling time	A _{VD} = − 1, 10-V step	To 0.1%	0.34		0.34		μs		
			To 0.01%	0.4		0.4				
V _n	Equivalent input noise voltage	R _S = 20 Ω, f = 10 Hz		15		15		nV/√Hz		
		R _S = 20 Ω, f = 1 kHz		10.5		10.5				
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		0.48		0.48		μV		
		f = 0.1 Hz to 10 Hz		0.51		0.51				
I _n	Equivalent input noise current	f = 10 Hz		1.89		1.89		pA/√Hz		
		f = 1 kHz		0.47		0.47				
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 20 V, A _{VD} = 10,	R _L = 2 kΩ, f = 10 kHz	0.01%		0.01%				
B ₁	Unity-gain bandwidth	R _L = 2 kΩ,	C _L = 100 pF	6		6		MHz		
	Gain-bandwidth product	R _L = 2 kΩ, f = 100 kHz	C _L = 100 pF,	5.9		5.9		MHz		
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 20 V, A _{VD} = 1,	R _L = 2 kΩ, C _L = 100 pF	668		668		kHz		
φ _m	Phase margin at unity gain	R _L = 2 kΩ,	C _L = 100 pF	58°		58°				

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TLE2142M electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142M			TLE2142AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ $R_S = 50\ \Omega$	25°C	220	1900		200	1500		μV
		Full range			2600			2200	
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range			200			200	
I_{IB} Input bias current		25°C	-0.8	-2		-0.8	-2		μA
		Full range			-2.3			-2.3	
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	-0.3 to 3.2		0 to 3	-0.3 to 3.2		V
		Full range	0 to 2.7	-0.3 to 2.9		0 to 2.7	-0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.4	3.7		3.4	3.7		
	$I_{OH} = 100\ \mu\text{A}$	Full range	3.75			3.75			
	$I_{OH} = 1\text{ mA}$		3.65			3.65			
	$I_{OH} = 10\text{ mA}$		3.45			3.45			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\text{ mA}$		150	225		150	225		
	$I_{OL} = 15\text{ mA}$		1.2	1.4		1.2	1.4		V
	$I_{OL} = 100\ \mu\text{A}$	Full range	200			200			mV
	$I_{OL} = 1\text{ mA}$		250			250			
	$I_{OL} = 10\text{ mA}$		1.25			1.25			V
A_{VD} Large-signal differential voltage amplification	$V_{IC} = \pm 2.5\text{ V}$, $V_O = 1\text{ V to } -1.5\text{ V}$ $R_L = 2\text{ k}\Omega$	25°C	50	220		50	220		V/mV
		Full range	5			5			
r_i Input resistance		25°C	70			70			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ No load,	25°C	6.6	8.8		6.6	8.8		mA
		Full range			9.2			9.2	

† Full range is -55°C to 125°C.

TLE2142M operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142M			TLE2142AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 500\text{ pF}$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise volt- age	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise cur- rent	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $R_L = 2\text{ k}\Omega^\dagger$, $A_{VD} = 2$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}$	5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$	5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $R_L = 2\text{ k}\Omega^\dagger$, $A_{VD} = 1$, $C_L = 100\text{ pF}$		660			660			kHz
ϕ_m	Phase margin	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}$	57°			57°			

$^\dagger R_L$ terminates at 2.5 V.

TLE214x, TLE214xA

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TLE2142M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142M			TLE2142AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50 \Omega$	25°C	290	1200		275	750		μV
		Full range		2000			1600		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		250			250		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.8			–1.8		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.7	–15.3 to 12.9		–15 to 12.7	–15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5$ mA		13.7	14		13.7	14		
	$I_O = -15$ mA		13.3	13.7		13.3	13.7		
	$I_O = -100 \mu A$	Full range	13.7			13.7			
	$I_O = -1$ mA		13.6			13.6			
	$I_O = -10$ mA		13.3			13.3			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
	$I_O = 1.5$ mA		–14.5	–14.8		–14.5	–14.8		
	$I_O = 15$ mA		–13.4	–13.8		–13.4	–13.8		
	$I_O = 100 \mu A$	Full range	–14.6			–14.6			
	$I_O = 1$ mA		–14.5			–14.5			
	$I_O = 10$ mA		–13.4			–13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 2$ k Ω	25°C	100	450		100	450		V/mV
		Full range	20			20			
r_i Input resistance		25°C	65			65			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50 \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	–25	–50		–25	–50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0, V_{IC} = 2.5$ V No load,	25°C	6.9	9		6.9	9		mA
		Full range		9.4			9.4		

† Full range is $-55^\circ C$ to $125^\circ C$.

TLE2142M operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142M			TLE2142AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	R _L = 2 kΩ, A _{VD} = − 1, C _L = 100 pF		27	45		27	45	V/μs	
SR −	Negative slew rate			27	42		27	42		
t _s	Settling time	A _{VD} = − 1, 10-V step	To 0.1%	0.34			0.34			μs
			To 0.01%	0.4			0.4			
V _n	Equivalent input noise voltage	R _S = 20 Ω, f = 10 Hz		15			15			nV/√Hz
		R _S = 20 Ω, f = 1 kHz		10.5			10.5			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		0.48			0.48			μV
		f = 0.1 Hz to 10 Hz		0.51			0.51			
I _n	Equivalent input noise current	f = 10 Hz		1.89			1.89			pA/√Hz
		f = 1 kHz		0.47			0.47			
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 20 V, R _L = 2 kΩ, A _{VD} = 10, f = 10 kHz	0.01%			0.01%				
B ₁	Unity-gain bandwidth	R _L = 2 kΩ, C _L = 100 pF	6			6			MHz	
	Gain-bandwidth product	R _L = 2 kΩ, C _L = 100 pF, f = 100 kHz	5.9			5.9			MHz	
B _{OM}	Maximum output-swing band-width	V _{O(PP)} = 20 V, R _L = 2 kΩ, A _{VD} = 1, C _L = 100 pF	668			668			kHz	
φ _m	Phase margin at unity gain	R _L = 2 kΩ, C _L = 100 pF	58°			58°				

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TLE2144M electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2144M			TLE2144AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ $R_S = 50\ \Omega$	25°C	0.5	3.8		0.5	3		mV
		Full range		5.2			4.4		
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range		250			250		
I_{IB} Input bias current		25°C	–0.8	–2		–0.8	–2		μA
		Full range		–2.3			–2.3		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	–0.3 to 3.2		0 to 3	–0.3 to 3.2		V
		Full range	0 to 2.7	–0.3 to 2.9		0 to 2.7	–0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.4	3.7		3.4	3.7		
	$I_{OH} = 100\ \mu\text{A}$	Full range	3.75			3.75			
	$I_{OH} = 1\text{ mA}$		3.65			3.65			
	$I_{OH} = 10\text{ mA}$		3.45			3.45			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\ \mu\text{A}$		150	225		150	225		
	$I_{OL} = 15\text{ mA}$		1.2	1.6		1.2	1.6		V
	$I_{OL} = 100\ \mu\text{A}$	Full range	200			200			mV
	$I_{OL} = 1\text{ mA}$		250			250			
	$I_{OL} = 10\text{ mA}$		1.45			1.45			V
A_{VD} Large-signal differential voltage amplification	$V_{IC} = \pm 2.5\text{ V}$, $V_O = 1\text{ V to } -1.5\text{ V}$ $R_L = 2\text{ k}\Omega$	25°C	50	95		50	95		V/mV
		Full range	5			5			
r_i Input resistance		25°C		70			70		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ No load,	25°C	13.2	17.6		13.2	17.6		mA
		Full range		18.4			18.4		

† Full range is -55°C to 125°C .

TLE2144M operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144M			TLE2144AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 500\text{ pF}$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$	15			15			nV/ $\sqrt{\text{Hz}}$	
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$	10.5			10.5				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$, $R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	5.9			5.9			MHz	
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$, $f = 100\text{ kHz}$	5.8			5.8			MHz	
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega^\dagger$	660			660			kHz	
ϕ_m	Phase margin	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	57°			57°				

[†] R_L terminates at 2.5 V

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TLE2144M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2144M			TLE2144AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50 \Omega$	25°C	0.6	2.4		0.5	1.5		mV
		Full range			4			3.2	
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		250			250		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.8			–1.8		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.7	–15.3 to 12.9		–15 to 12.7	–15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5$ mA		13.7	14		13.7	14		
	$I_O = -15$ mA		13.1	13.7		13.1	13.7		
	$I_O = -100 \mu A$	Full range	13.7			13.7			
	$I_O = -1$ mA		13.6			13.6			
	$I_O = -10$ mA		13.1			13.1			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
	$I_O = 1.5$ mA		–14.5	–14.8		–14.5	–14.8		
	$I_O = 15$ mA		–13.4	–13.8		–13.4	–13.8		
	$I_O = 100 \mu A$	Full range	–14.6			–14.6			
	$I_O = 1$ mA		–14.5			–14.5			
	$I_O = 10$ mA		–13.4			–13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 2$ k Ω	25°C	100	170		100	170		V/mV
		Full range	20			20			
r_i Input resistance		25°C		65			65		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50 \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	–25	–50		–25	–50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0, V_{IC} = 2.5$ V	25°C		13.8	18		13.8	18	mA
		Full range			18.8			18.8	

† Full range is $-55^\circ C$ to $125^\circ C$

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TLE2144M operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144M			TLE2144AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	$A_{VD} = -1$,	27	45		27	45		V/ μs
SR–	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%		0.34			0.34		μs
			To 0.01%		.4			.4		
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$,	$f = 10\text{ Hz}$		15			15		nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$,	$f = 1\text{ kHz}$		10.5			10.5		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$			0.48			0.48		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			0.51			0.51		
I_n	Equivalent input noise current	$f = 10\text{ Hz}$			1.89			1.89		pA/ $\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$			0.47			0.47		
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$,	$R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$		0.01%			0.01%		
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$		6			6		MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$,		5.9			5.9		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$		668			668		kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$		58°			58°		

TLE214x, TLE214xA

EXCALIBUR LOW-NOISE HIGH-SPEED

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TLE2141Y electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TLE2141Y			UNIT
		MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $R_S = 50\ \Omega$, $V_O = 0$		200	1000	μV
I_{IO} Input offset current			7	100	nA
I_{IB} Input bias current			-0.7	-1.5	μA
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	-15 to 13	-15.3 to 13.2		V
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150\ \mu\text{A}$	13.8	14.1		V
	$I_O = -1.5\ \text{mA}$	13.7	14		
	$I_O = -15\ \text{mA}$	13.3	13.7		
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150\ \mu\text{A}$	-14.7	-14.9		V
	$I_O = 1.5\ \text{mA}$	-14.5	-14.8		
	$I_O = 15\ \text{mA}$	-13.4	-13.8		
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$, $R_L = 2\ \text{k}\Omega$	100	450		V/mV
r_i Input resistance			65		M Ω
c_i Input capacitance			2.5		pF
z_o Open-loop output impedance	$f = 1\ \text{MHz}$		30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	80	108		dB
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\ \text{V}$ to $\pm 15\ \text{V}$, $R_S = 50\ \Omega$	85	106		dB
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1\ \text{V}$	-25	-50	mA
		$V_{ID} = -1\ \text{V}$	20	31	
I_{CC} Supply current	$V_O = 0$, No load		3.5	4.5	mA

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TLE2142Y electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	TLE2142Y			UNIT
			MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{IC} = 0$, $V_O = 0$ $R_S = 50\ \Omega$		150	875	μV
I_{IO}	Input offset current			7	100	nA
I_{IB}	Input bias current			-0.7	-1.5	μA
V_{ICR}	Common-mode input voltage range	$R_S = 50\ \Omega$	-15 to 13	-15.3 to 13.2		V
V_{OM+}	Maximum positive peak output voltage swing	$I_O = -150\ \mu\text{A}$	13.8	14.1		V
		$I_O = -1.5\text{ mA}$	13.7	14		
		$I_O = -15\text{ mA}$	13.3	13.7		
V_{OM-}	Maximum negative peak output voltage swing	$I_O = 150\ \mu\text{A}$	-14.7	-14.9		V
		$I_O = 1.5\text{ mA}$	-14.5	-14.8		
		$I_O = 15\text{ mA}$	-13.4	-13.8		
A_{VD}	Large-signal differential voltage amplification	$V_O = \pm 10\text{ V}$, $R_L = 2\text{ k}\Omega$	100	450		V/mV
r_i	Input resistance			65		M Ω
c_i	Input capacitance			2.5		pF
z_o	Open-loop output impedance	$f = 1\text{ MHz}$		30		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	80	108		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	85	106		dB
I_{OS}	Short-circuit output current	$V_O = 0$	$V_{ID} = 1\text{ V}$	-25	-50	mA
			$V_{ID} = -1\text{ V}$	20	31	
I_{CC}	Supply current	$V_O = 0$, No load		6.9	9	mA

TLE214x, TLE214xA

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TLE2144Y electrical characteristics at $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TLE2144Y			UNIT
		MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$ $R_S = 50\ \Omega$,		0.3	1.8	mV
I_{IO} Input offset current			7	100	nA
I_{IB} Input bias current			-0.7	-1.5	μA
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	-15 to 13	-15.3 to 13.2		V
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150\ \mu\text{A}$	13.8	14.1		V
	$I_O = -1.5\text{ mA}$	13.7	14		
	$I_O = -15\text{ mA}$	13.3	13.7		
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150\ \mu\text{A}$	-14.7	-14.9		V
	$I_O = 1.5\text{ mA}$	-14.5	-14.8		
	$I_O = 15\text{ mA}$	-13.4	-13.8		
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\text{ V}$, $R_L = 2\text{ k}\Omega$	100	450		V/mV
r_i Input resistance			65		$\text{M}\Omega$
c_i Input capacitance			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$		30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	80	108		dB
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	85	106		dB
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1\text{ V}$	-25	-50	mA
		$V_{ID} = -1\text{ V}$	20	31	
I_{CC} Supply current	$V_O = 0$, No load		13.8	18	mA

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	Distribution	1, 2, 3
I_{IO}	Input offset current	vs Free-air temperature	4
I_{IB}	Input bias current	vs Common-mode input voltage vs Free-air temperature	5 6
V_{OM+}	Maximum positive peak output voltage	vs Supply voltage vs Free-air temperature vs Output current vs Settling time	7 8 9 11
V_{OM-}	Maximum negative peak output voltage	vs Supply voltage vs Free-air temperature vs Output current vs Settling time	7 8 10 11
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	12
V_{OH}	High-level output voltage	vs Output current	13
V_{OL}	Low-level output voltage	vs Output current	14
A_{VD}	Large-signal differential voltage amplification	vs Frequency vs Free-air temperature	15 16
z_o	Closed-loop output impedance	vs Frequency	17
I_{OS}	Short-circuit output current	vs Free-air temperature	18
CMRR	Common-mode rejection ratio	vs Frequency vs Free-air temperature	19 20
k_{SVR}	Supply-voltage rejection ratio	vs Frequency vs Free-air temperature	21 22
I_{CC}	Supply current	vs Supply voltage vs Free-air temperature	23 24
V_n	Equivalent input noise voltage	vs Frequency	25
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I_n	Noise current	vs Frequency	27
THD + N	Total harmonic distortion plus noise	vs Frequency	28
SR	Slew rate	vs Free-air temperature vs Load capacitance	29 30
Pulse response	Noninverting large signal	vs Time	31
	Inverting large signal	vs Time	32
	Small signal	vs Time	33
B_1	Unity-gain bandwidth	vs Load capacitance	34
	Gain margin	vs Load capacitance	35
ϕ_m	Phase margin	vs Load capacitance	36
	Phase shift	vs Frequency	15

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TYPICAL CHARACTERISTICS

**TLE2141
DISTRIBUTION OF
INPUT OFFSET VOLTAGE**

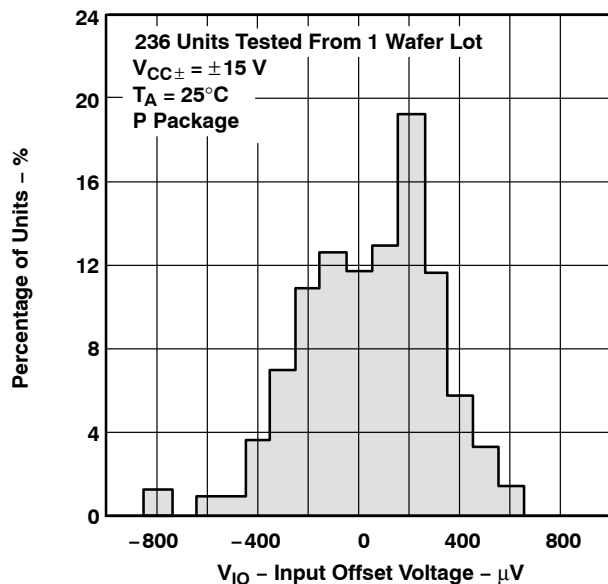


Figure 1

**TLE2142
DISTRIBUTION OF
INPUT OFFSET VOLTAGE**

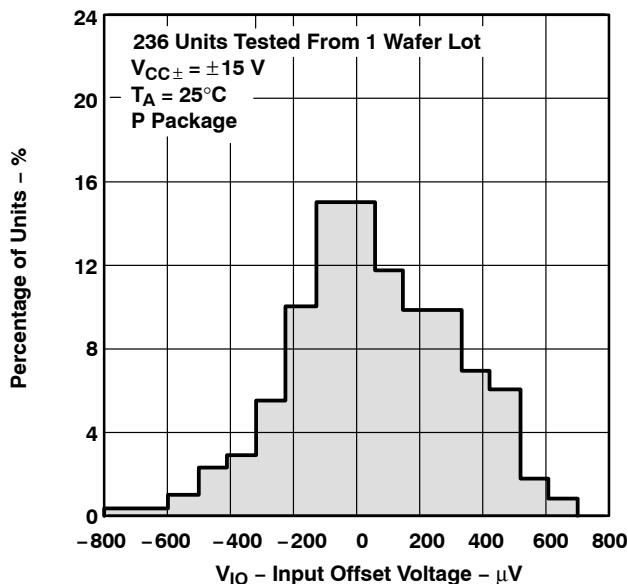


Figure 2

**TLE2144
DISTRIBUTION OF
INPUT OFFSET VOLTAGE**

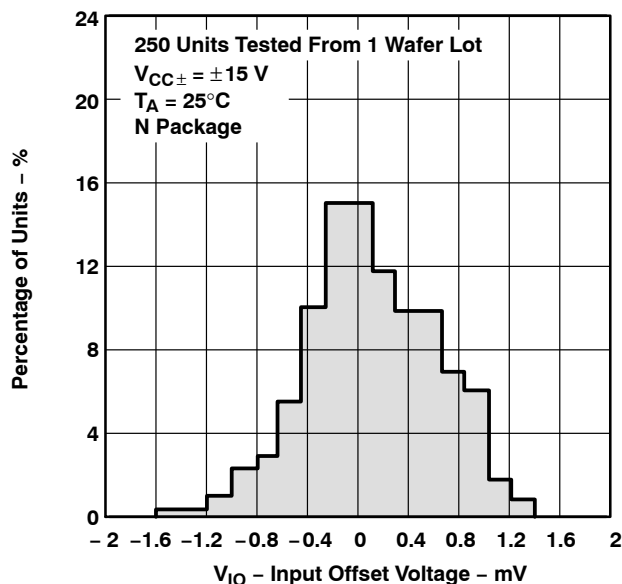


Figure 3

**INPUT OFFSET CURRENT[†]
vs
FREE-AIR TEMPERATURE**

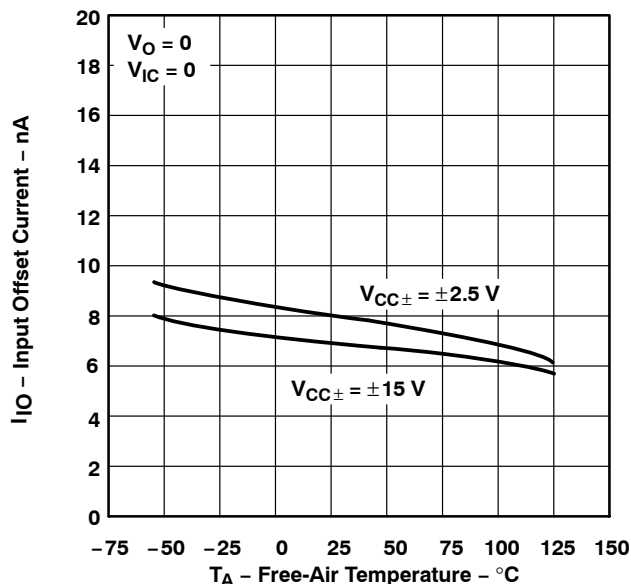
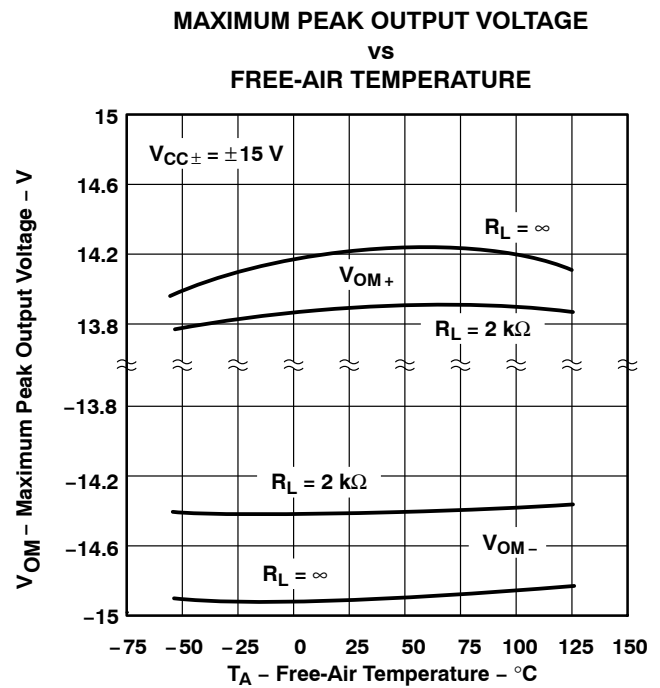
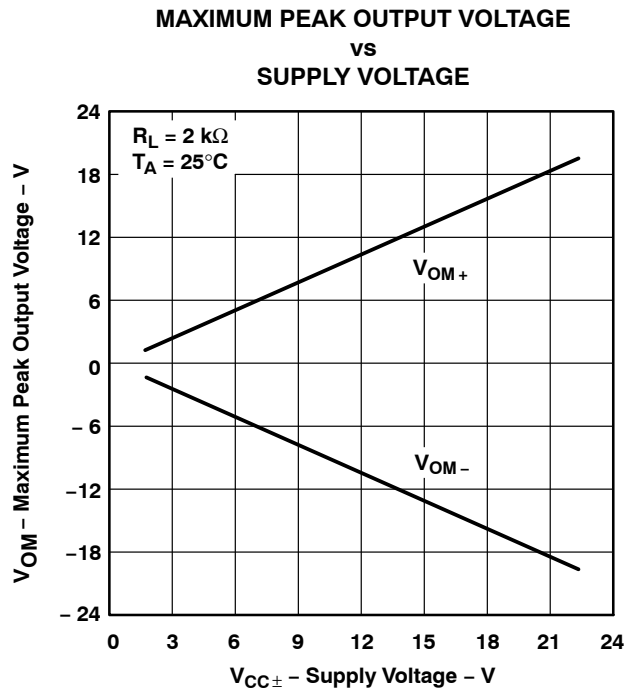
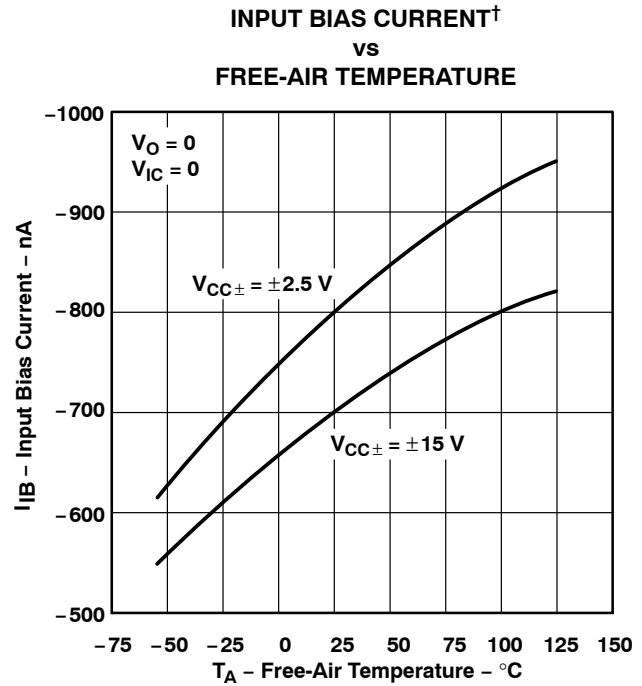
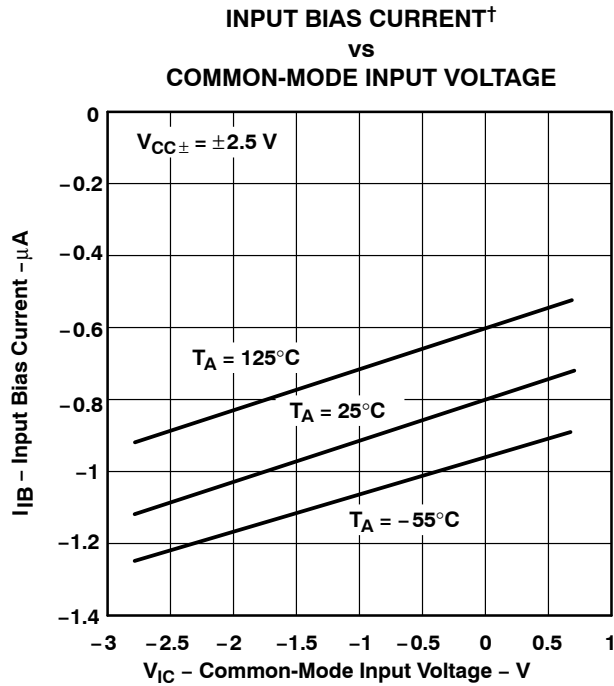


Figure 4

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS



[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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TYPICAL CHARACTERISTICS

MAXIMUM POSITIVE PEAK
OUTPUT VOLTAGE[†]
vs
OUTPUT CURRENT

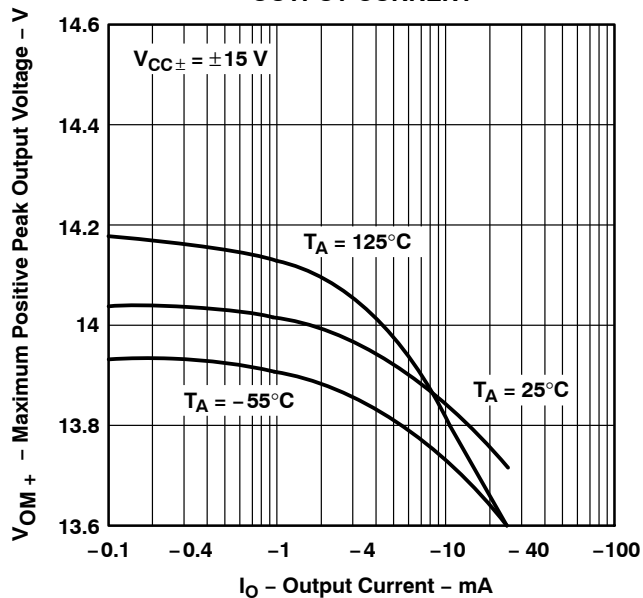


Figure 9

MAXIMUM NEGATIVE PEAK
OUTPUT VOLTAGE[†]
vs
OUTPUT CURRENT

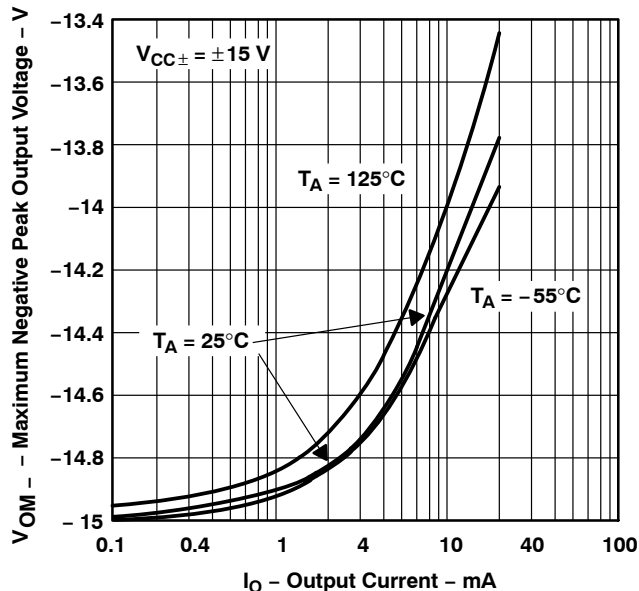


Figure 10

MAXIMUM PEAK OUTPUT VOLTAGE
vs
SETTLING TIME

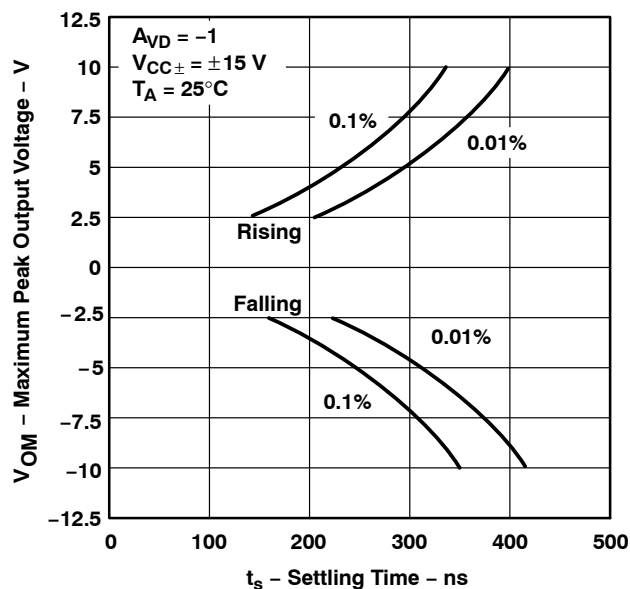


Figure 11

MAXIMUM PEAK-TO-PEAK
OUTPUT VOLTAGE[†]
vs
FREQUENCY

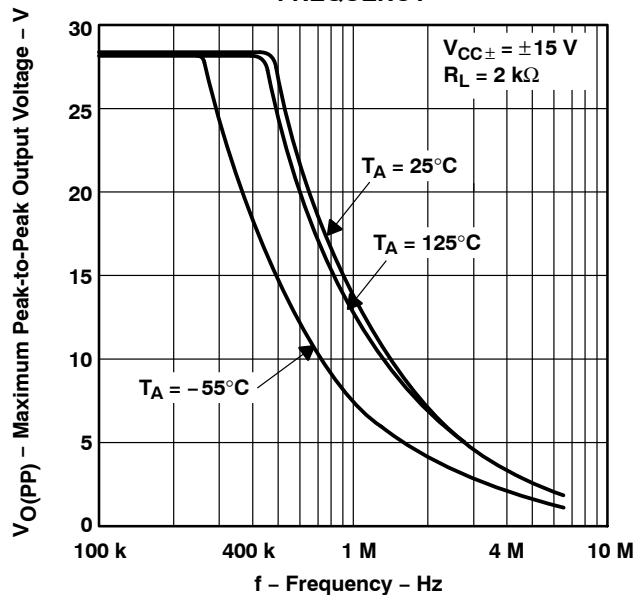
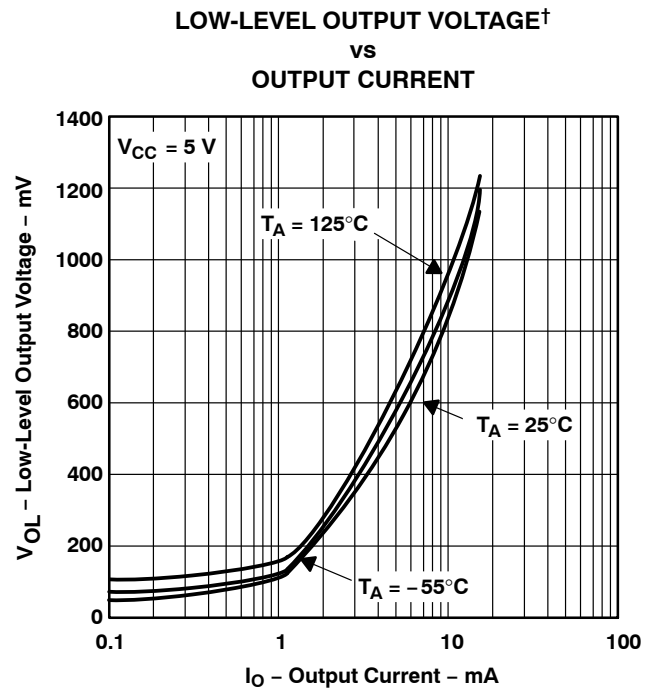
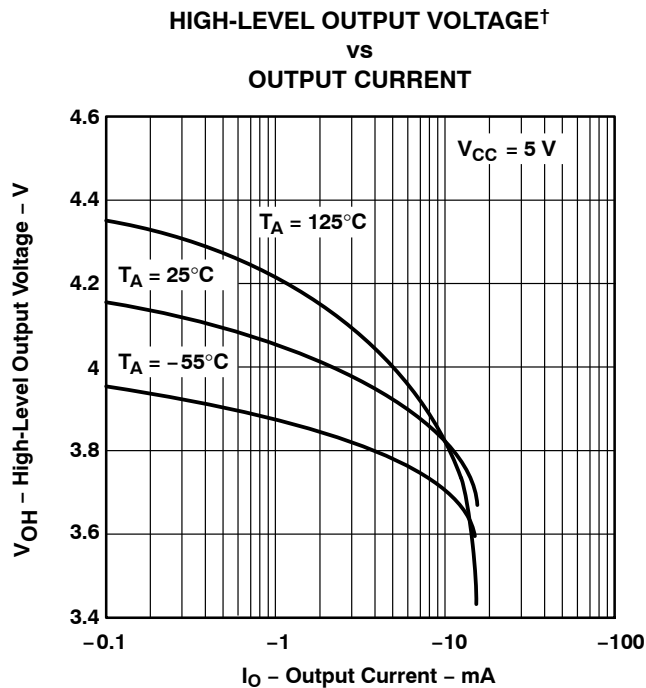


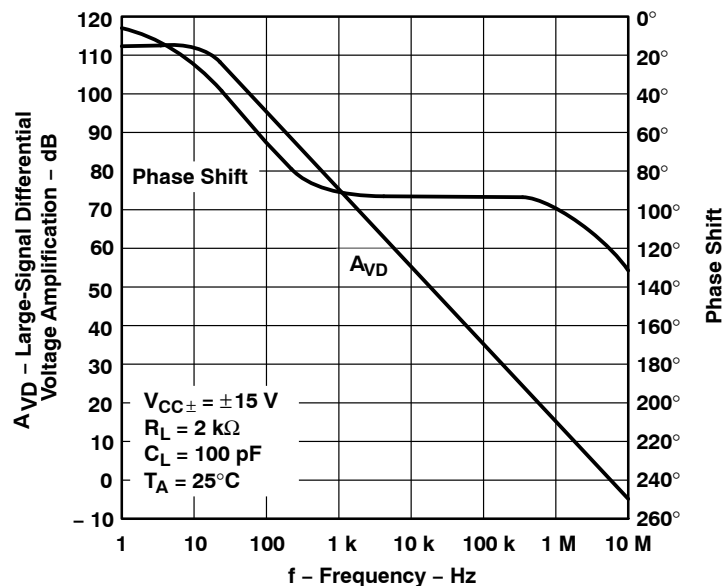
Figure 12

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS



LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT vs FREQUENCY



[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION†

vs

FREE-AIR TEMPERATURE

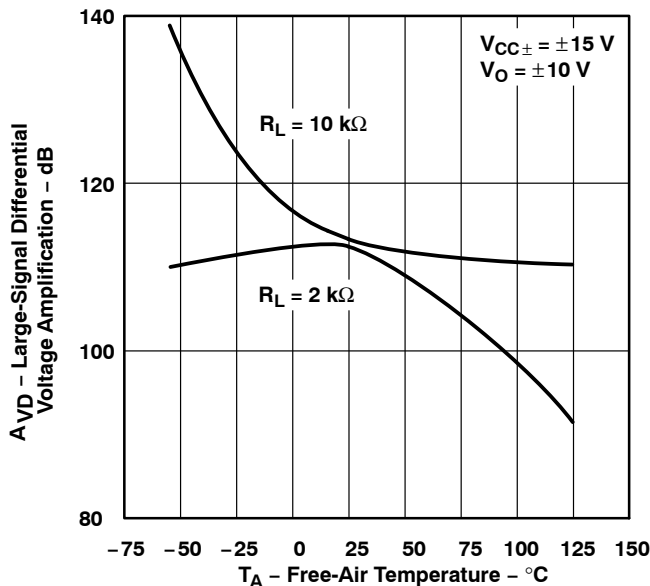


Figure 16

CLOSED-LOOP OUTPUT IMPEDANCE

vs

FREQUENCY

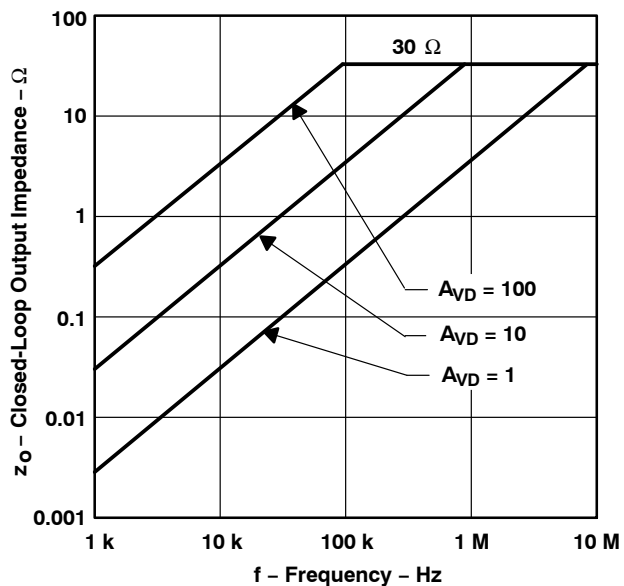


Figure 17

SHORT-CIRCUIT OUTPUT CURRENT†

vs

FREE-AIR TEMPERATURE

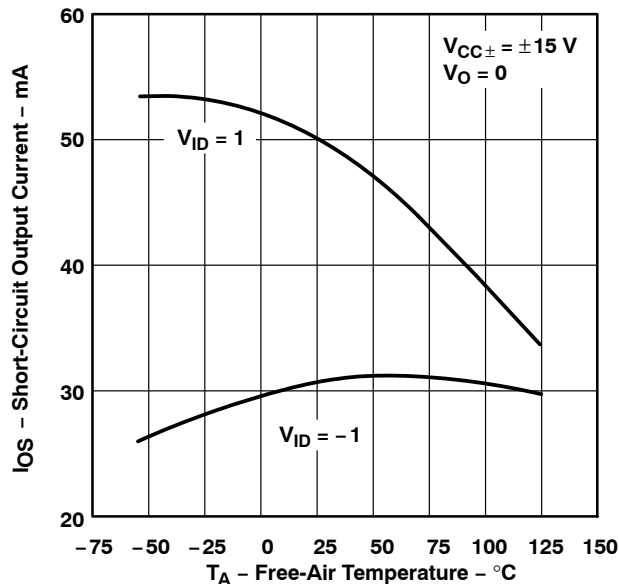


Figure 18

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

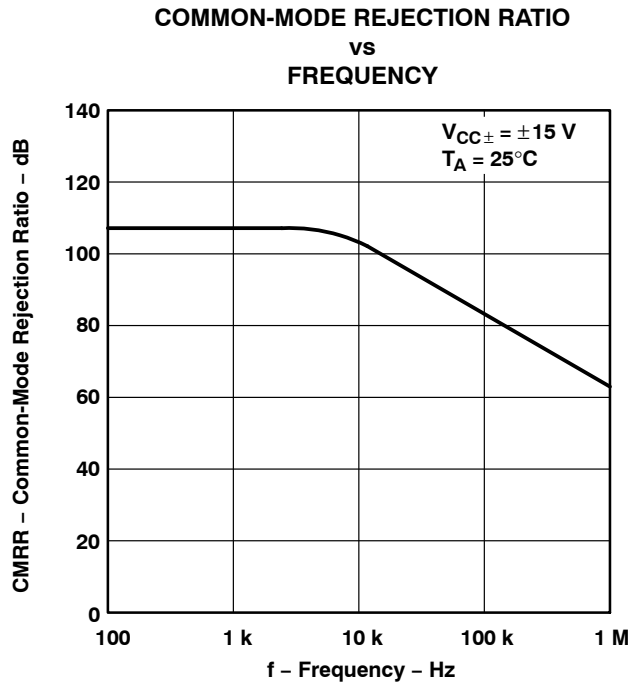


Figure 19

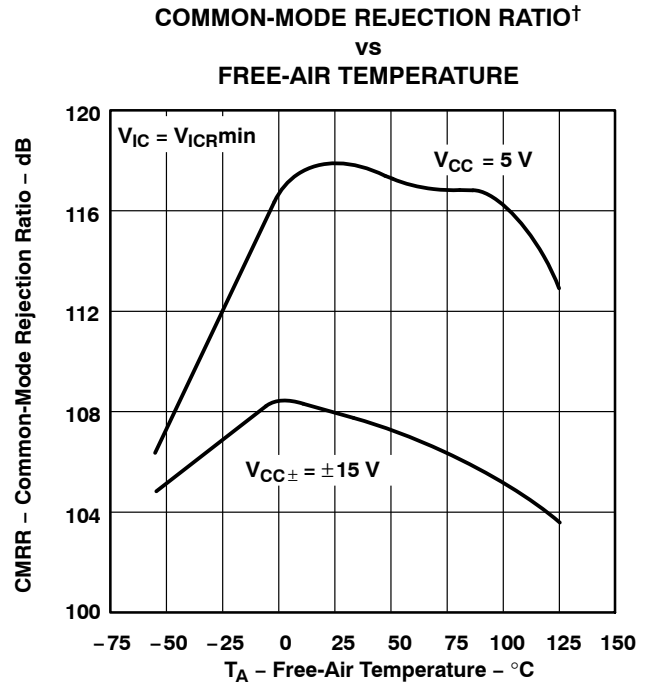


Figure 20

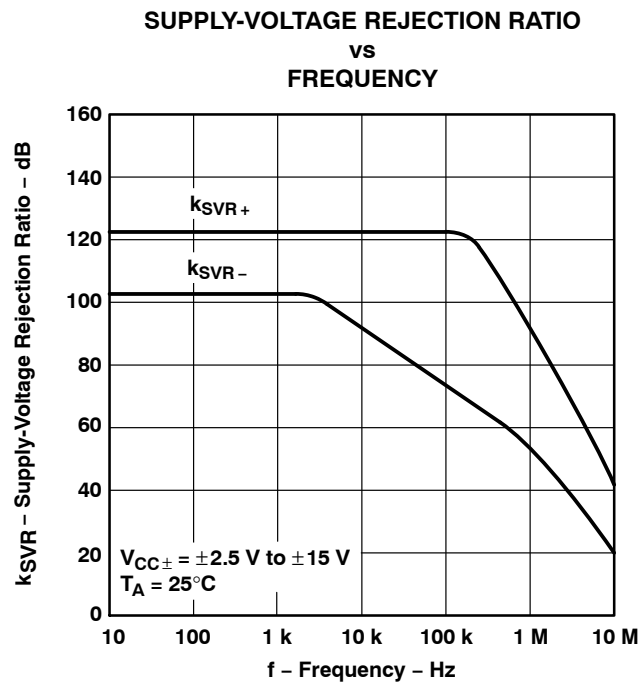


Figure 21

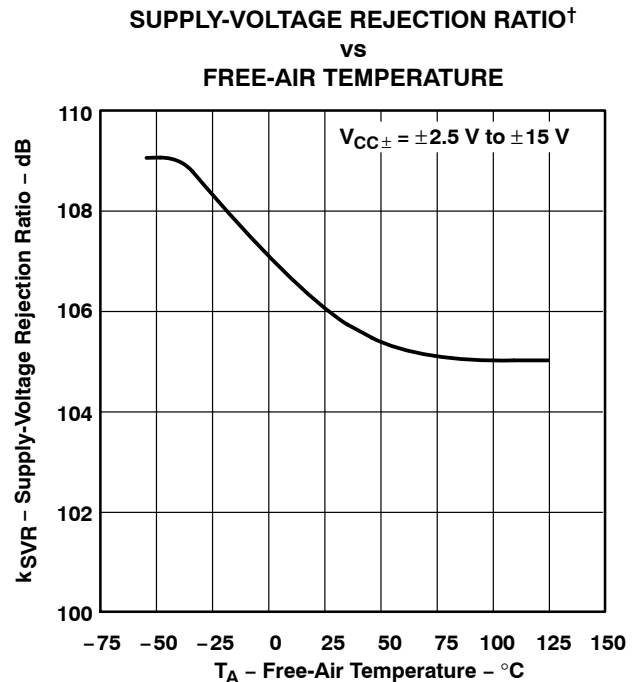


Figure 22

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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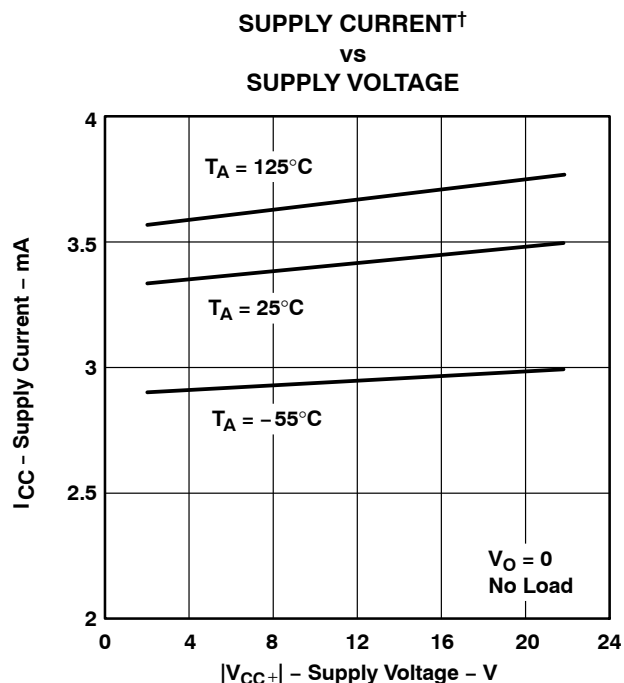


Figure 23

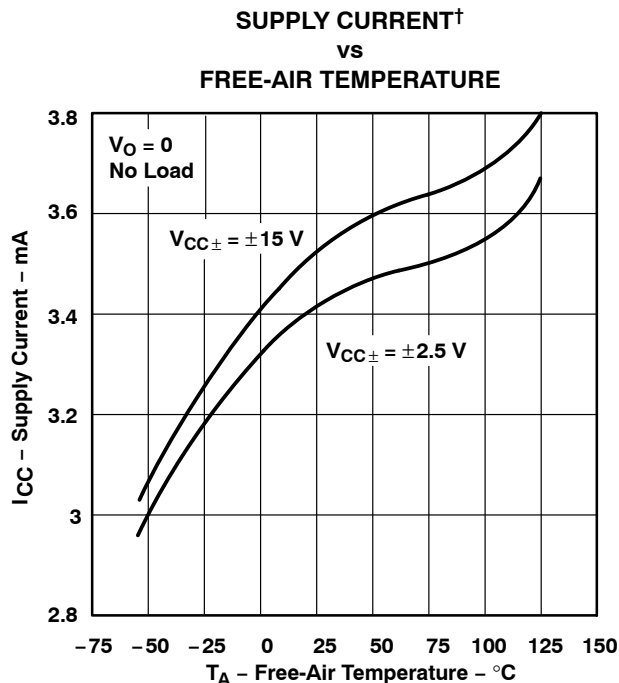


Figure 24

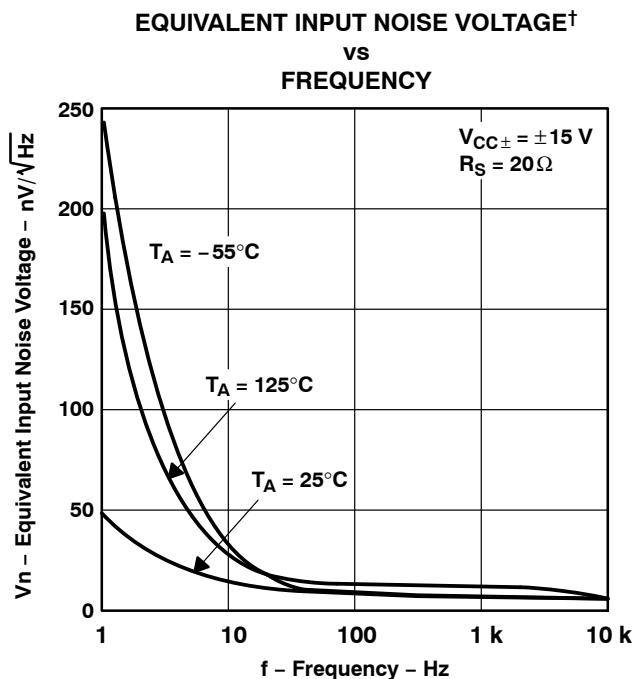


Figure 25

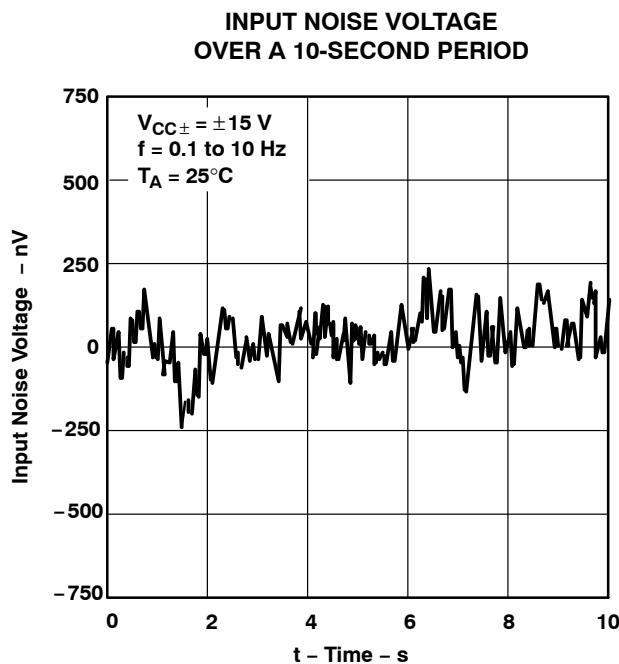
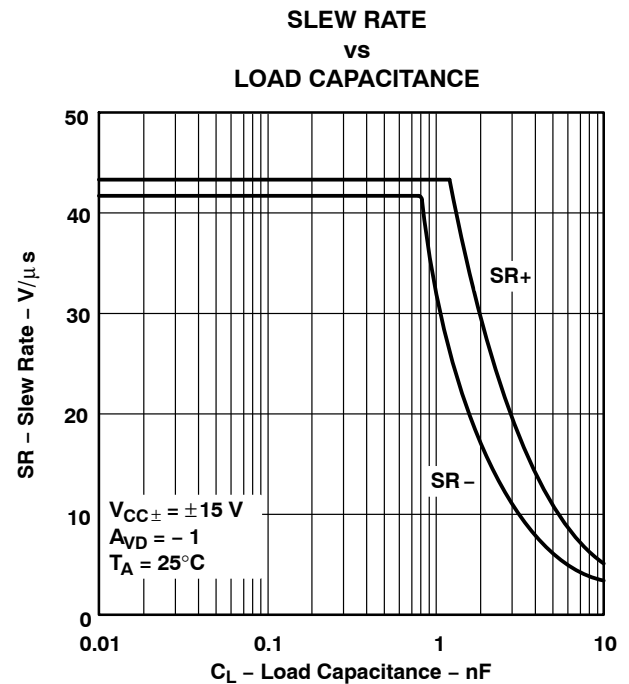
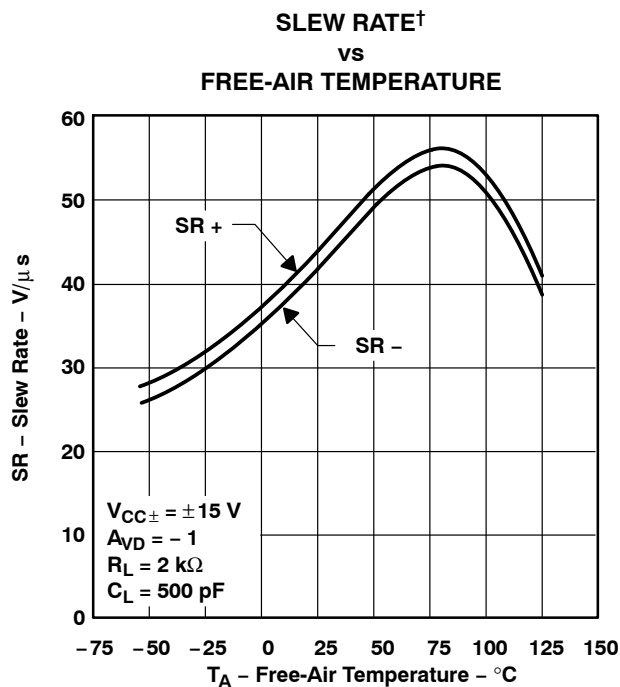
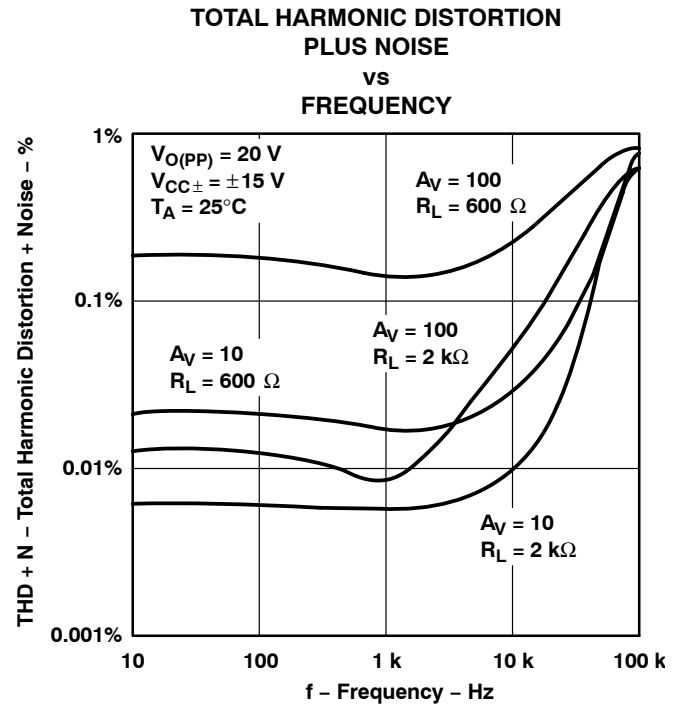
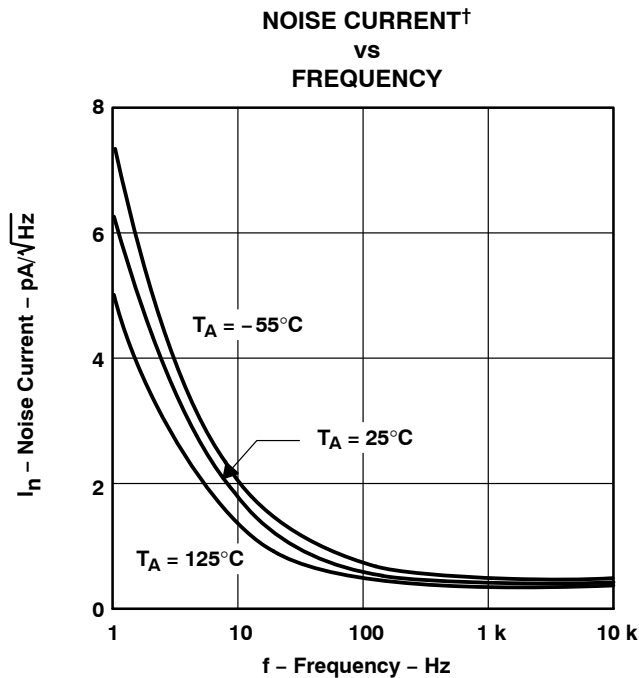


Figure 26

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

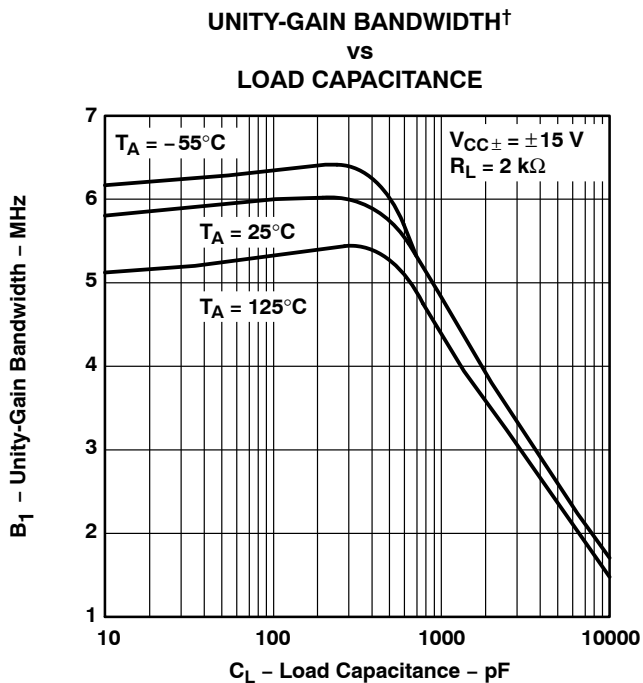
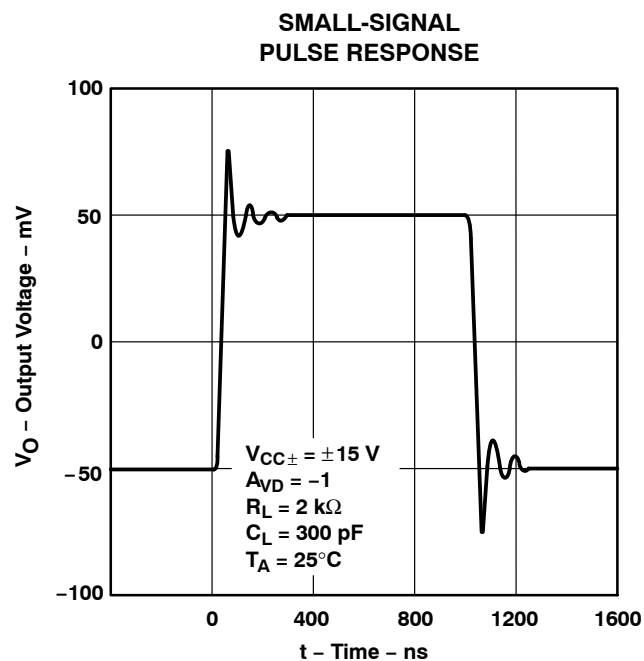
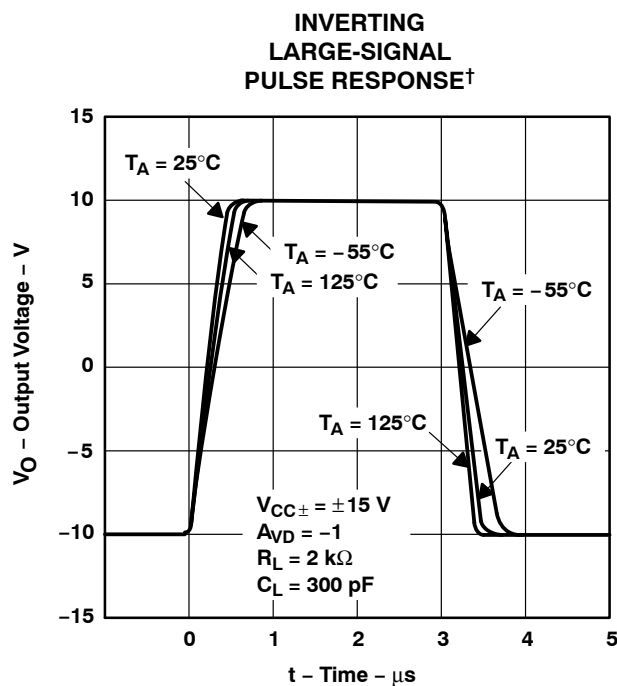
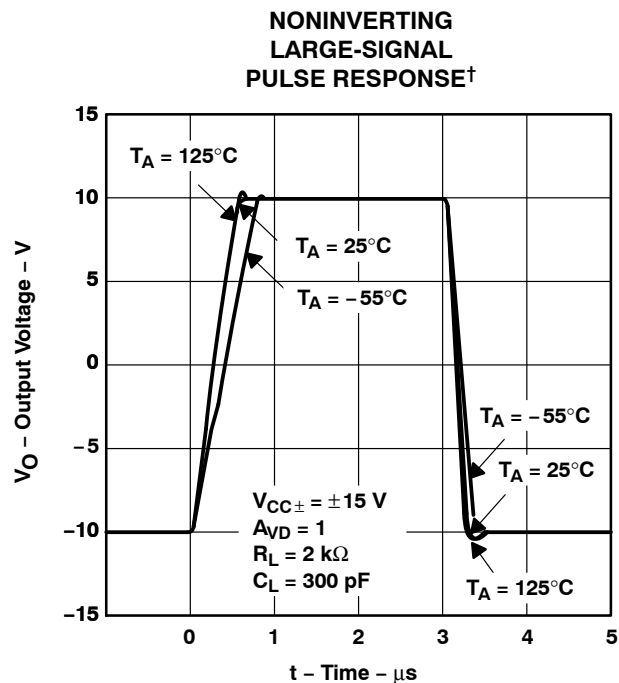


[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

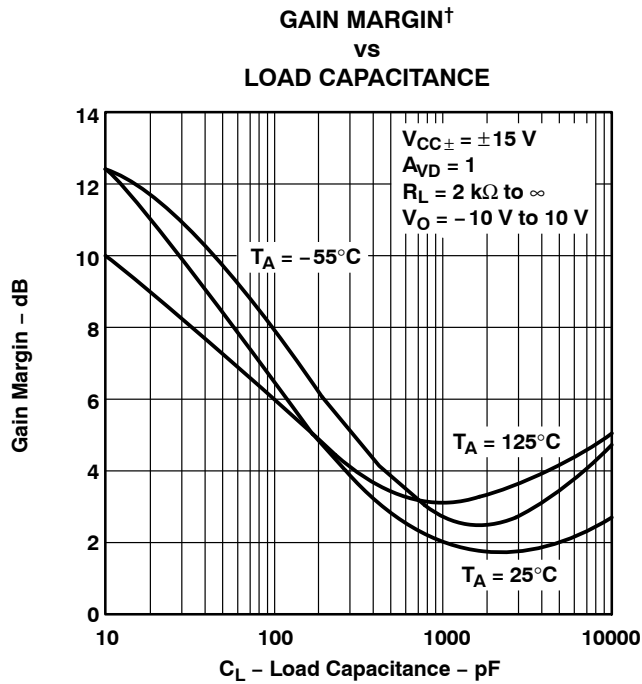


Figure 35

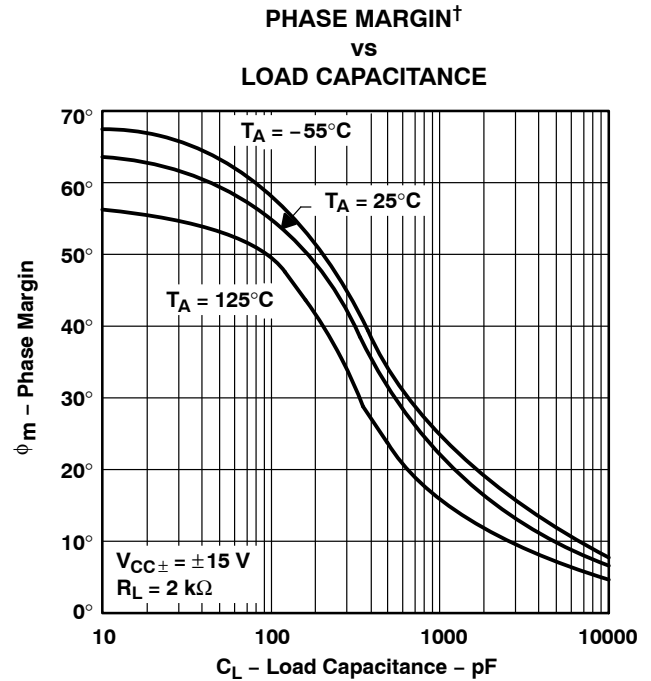


Figure 36

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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APPLICATION INFORMATION

input offset voltage nulling

The TLE2141 series offers external null pins that can be used to further reduce the input offset voltage. If this feature is desired, connect the circuit of Figure 37 as shown. If external nulling is not needed, the null pins may be left unconnected.

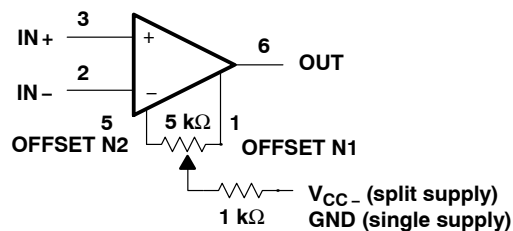


Figure 37. Input Offset Voltage Null Circuit

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-9321603Q2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9321603Q2A TLE2142MFKB
5962-9321603QHA	Active	Production	CFP (U) 10	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321603QHA TLE2142M
5962-9321603QPA	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321603QPA TLE2142M
5962-9321604Q2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9321604Q2A TLE2142 AMFKB
5962-9321604QHA	Active	Production	CFP (U) 10	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321604QHA TLE2142AM
5962-9321604QPA	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321604QPA TLE2142AM
5962-9321605Q2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9321605Q2A TLE2144MFKB
5962-9321605QCA	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9321605QC A TLE2144MJB
5962-9321606Q2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9321606Q2A TLE2144 AMFKB
5962-9321606QCA	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9321606QC A TLE2144AMJB
TLE2141ACD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-	2141AC
TLE2141ACP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLE2141AC
TLE2141ACP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2141AC
TLE2141AID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-	2141AI
TLE2141AIDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2141AI
TLE2141AIDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2141AI

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLE2141AIP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2141AI
TLE2141AIP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2141AI
TLE2141CD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-	2141C
TLE2141CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2141C
TLE2141CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2141C
TLE2141CDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	-	Call TI	Call TI	See TLE2141CDR	
TLE2141CP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLE2141CP
TLE2141CP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	TLE2141CP
TLE2141ID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-	2141I
TLE2141IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2141I
TLE2141IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2141I
TLE2141IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-	TLE2141IP
TLE2141IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	TLE2141IP
TLE2141MD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2141M
TLE2141MD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2141M
TLE2141MDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2141M
TLE2141MDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2141M
TLE2142ACD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	2142AC
TLE2142ACDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2142AC
TLE2142ACDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2142AC
TLE2142AID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 85	2142AI
TLE2142AIDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	2142AI
TLE2142AIDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	2142AI
TLE2142AMD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-55 to 125	E2142A
TLE2142AMDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	E2142A
TLE2142AMDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	E2142A
TLE2142AMDRG4	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-	E2142A
TLE2142AMFKB	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9321604Q2A TLE2142 AMFKB

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLE2142AMFKB.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9321604Q2A TLE2142 AMFKB
TLE2142AMJG	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-	TLE2142AMJG
TLE2142AMJG.A	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TLE2142AMJG
TLE2142AMJGB	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321604QPA TLE2142AM
TLE2142AMJGB.A	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321604QPA TLE2142AM
TLE2142AMUB	Active	Production	CFP (U) 10	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321604QHA TLE2142AM
TLE2142AMUB.A	Active	Production	CFP (U) 10	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321604QHA TLE2142AM
TLE2142CD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	2142C
TLE2142CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2142C
TLE2142CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2142C
TLE2142CDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	-	Call TI	Call TI	0 to 70	
TLE2142CP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2142CP
TLE2142CP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2142CP
TLE2142CPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	Q2142
TLE2142CPWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	Q2142
TLE2142ID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 105	2142I
TLE2142IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	2142I
TLE2142IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	2142I
TLE2142IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 105	TLE2142IP
TLE2142IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 105	TLE2142IP
TLE2142MD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-55 to 125	2142M
TLE2142MDG4	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-	2142M
TLE2142MDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2142M
TLE2142MDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2142M

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLE2142MFKB	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9321603Q2A TLE2142MFKB
TLE2142MFKB.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9321603Q2A TLE2142MFKB
TLE2142MJGB	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321603QPA TLE2142M
TLE2142MJGB.A	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321603QPA TLE2142M
TLE2142MUB	Active	Production	CFP (U) 10	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321603QHA TLE2142M
TLE2142MUB.A	Active	Production	CFP (U) 10	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9321603QHA TLE2142M
TLE2144ACN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2144ACN
TLE2144ACN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2144ACN
TLE2144AIN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2144AIN
TLE2144AIN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TLE2144AIN
TLE2144AMFKB	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9321606Q2A TLE2144 AMFKB
TLE2144AMFKB.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9321606Q2A TLE2144 AMFKB
TLE2144AMJB	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9321606QC A TLE2144AMJB
TLE2144AMJB.A	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9321606QC A TLE2144AMJB
TLE2144CDW	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLE2144C
TLE2144CDW.A	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLE2144C
TLE2144CDWR	Active	Production	SOIC (DW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLE2144C

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLE2144CDWR.A	Active	Production	SOIC (DW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLE2144C
TLE2144CN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2144CN
TLE2144CN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLE2144CN
TLE2144IDW	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TLE2144I
TLE2144IDW.A	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TLE2144I
TLE2144IDWR	Active	Production	SOIC (DW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TLE2144I
TLE2144IDWR.A	Active	Production	SOIC (DW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	TLE2144I
TLE2144IN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 105	TLE2144IN
TLE2144IN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 105	TLE2144IN
TLE2144MDW	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	TLE2144M
TLE2144MDW.A	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	TLE2144M
TLE2144MDWG4	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-	TLE2144M
TLE2144MDWG4.A	Active	Production	SOIC (DW) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	TLE2144M
TLE2144MFKB	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9321605Q2A TLE2144MFKB
TLE2144MFKB.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9321605Q2A TLE2144MFKB
TLE2144MJB	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9321605QC A TLE2144MJB
TLE2144MJB.A	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9321605QC A TLE2144MJB

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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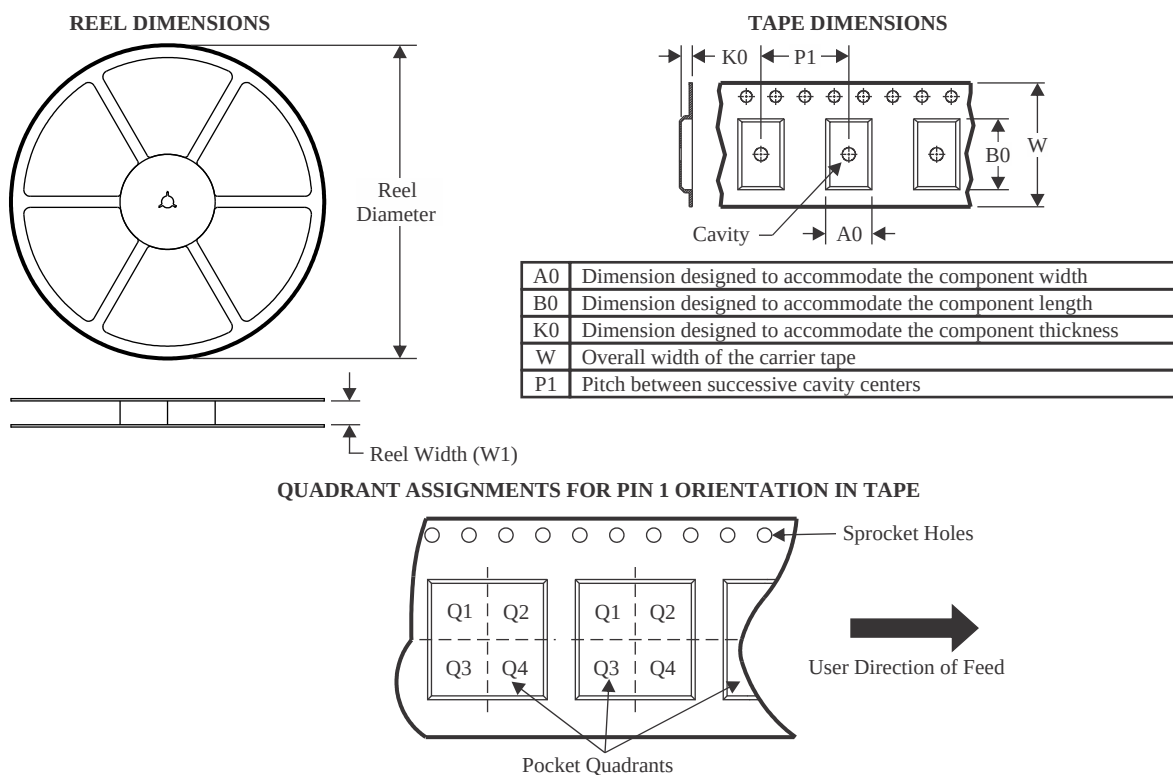
OTHER QUALIFIED VERSIONS OF TLE2141, TLE2141A, TLE2142, TLE2142A, TLE2142AM, TLE2142M, TLE2144, TLE2144A, TLE2144AM, TLE2144M :

- Catalog : [TLE2142A](#), [TLE2142](#), [TLE2144A](#), [TLE2144](#)
- Automotive : [TLE2141-Q1](#), [TLE2142-Q1](#), [TLE2142-Q1](#)
- Enhanced Product : [TLE2141-EP](#), [TLE2144-EP](#), [TLE2144-EP](#)
- Military : [TLE2141M](#), [TLE2141AM](#), [TLE2142M](#), [TLE2142AM](#), [TLE2144M](#), [TLE2144AM](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications

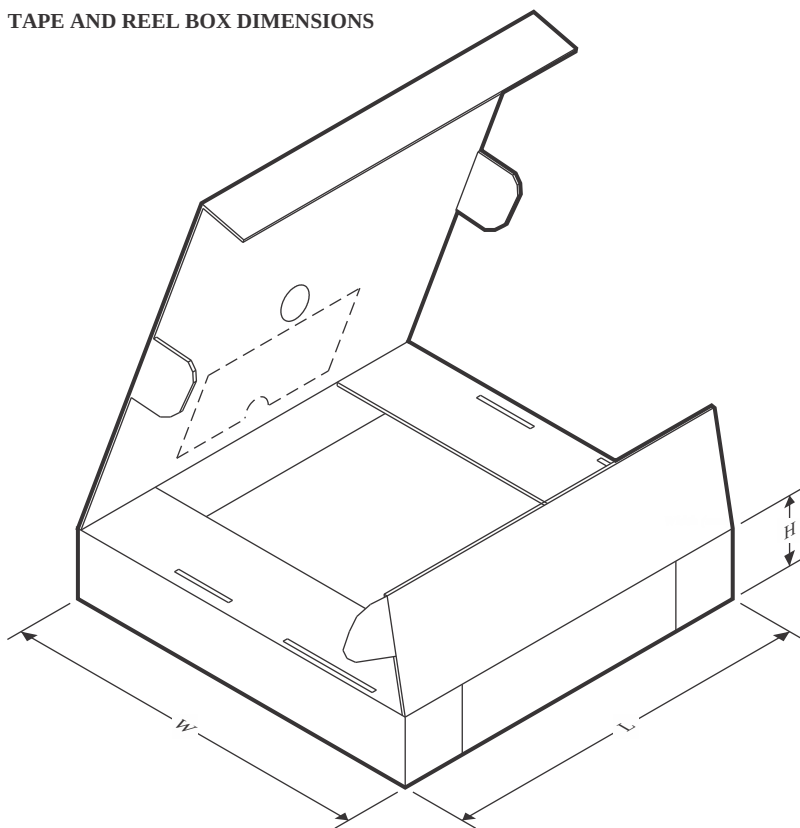
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLE2141AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2141CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2141IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2141MDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142AMDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142CPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLE2142IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142MDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2144CDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
TLE2144IDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

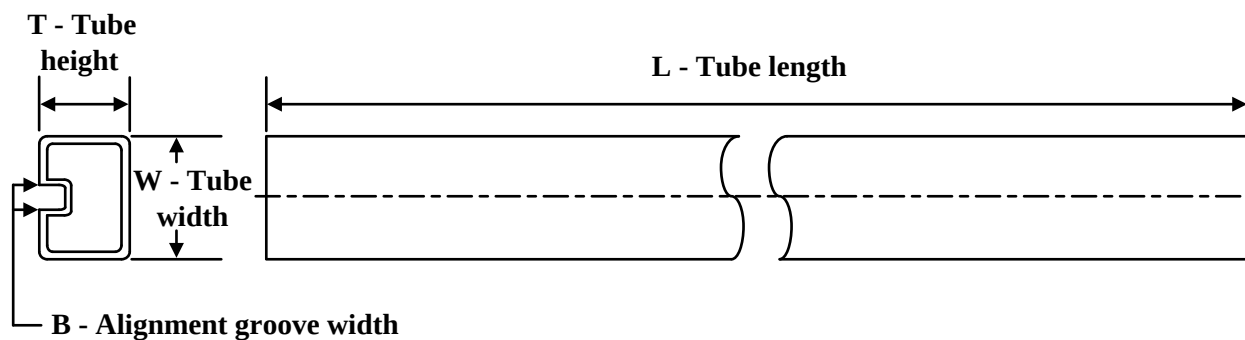
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLE2141AIDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2141CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2141IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2141MDR	SOIC	D	8	2500	350.0	350.0	43.0
TLE2142ACDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2142AIDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2142AMDR	SOIC	D	8	2500	350.0	350.0	43.0
TLE2142CDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2142CPWR	TSSOP	PW	16	2000	356.0	356.0	35.0
TLE2142IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLE2142MDR	SOIC	D	8	2500	350.0	350.0	43.0
TLE2144CDWR	SOIC	DW	16	2000	350.0	350.0	43.0
TLE2144IDWR	SOIC	DW	16	2000	350.0	350.0	43.0

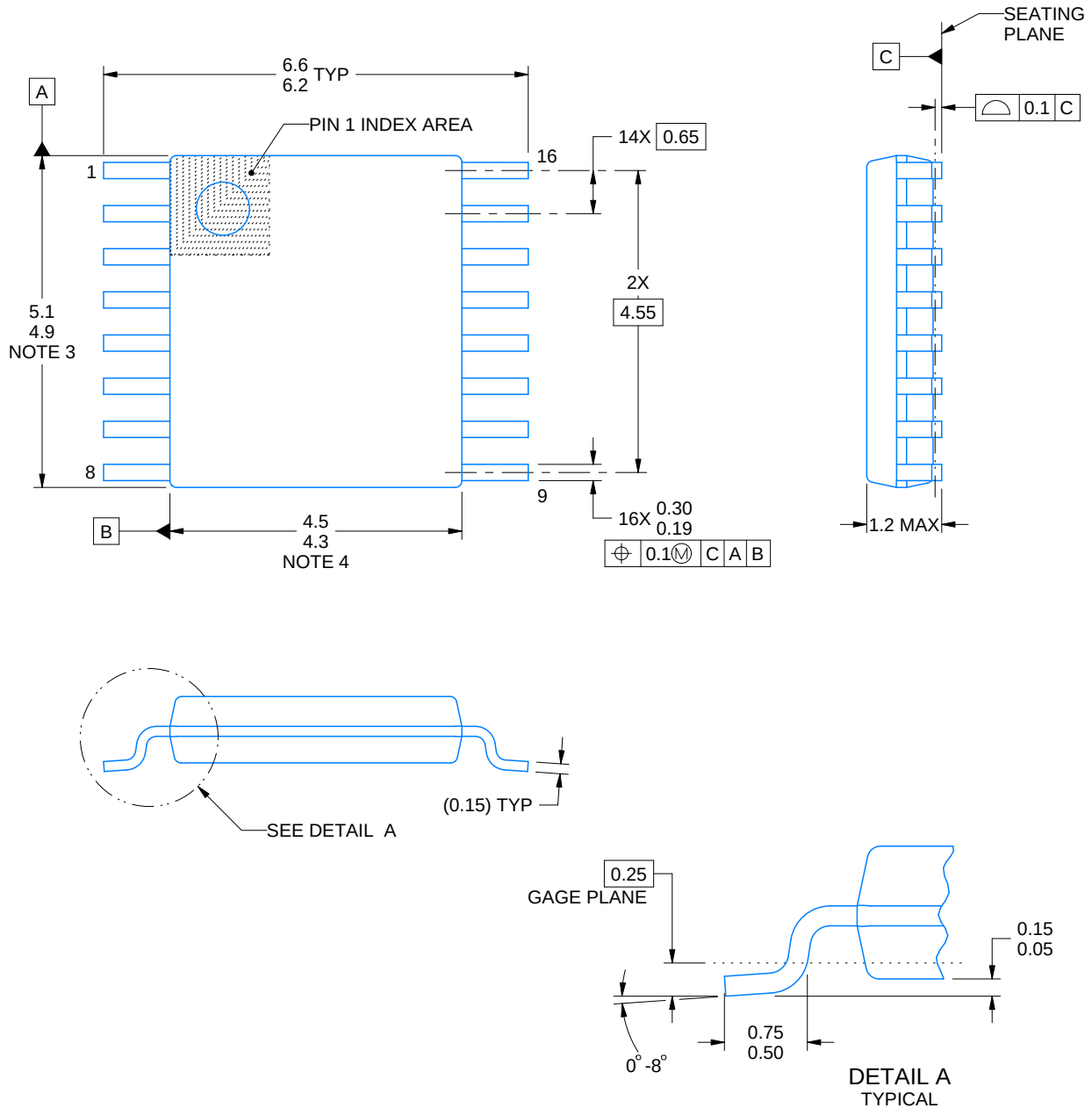
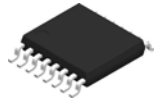
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
5962-9321603Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9321603QHA	U	CFP	10	25	506.98	26.16	6220	NA
5962-9321604Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9321604QHA	U	CFP	10	25	506.98	26.16	6220	NA
5962-9321605Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9321606Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
TLE2141ACP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2141ACP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2141AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2141AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2141CP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2141CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2141IP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2141IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2141MD	D	SOIC	8	75	505.46	6.76	3810	4
TLE2141MD.A	D	SOIC	8	75	505.46	6.76	3810	4
TLE2142AMFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
TLE2142AMFKB.A	FK	LCCC	20	55	506.98	12.06	2030	NA
TLE2142AMUB	U	CFP	10	25	506.98	26.16	6220	NA
TLE2142AMUB.A	U	CFP	10	25	506.98	26.16	6220	NA
TLE2142CP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2142CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2142IP	P	PDIP	8	50	506	13.97	11230	4.32
TLE2142IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLE2142MFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
TLE2142MFKB.A	FK	LCCC	20	55	506.98	12.06	2030	NA
TLE2142MUB	U	CFP	10	25	506.98	26.16	6220	NA
TLE2142MUB.A	U	CFP	10	25	506.98	26.16	6220	NA
TLE2144ACN	N	PDIP	14	25	506	13.97	11230	4.32

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLE2144ACN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLE2144AIN	N	PDIP	14	25	506	13.97	11230	4.32
TLE2144AIN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLE2144AMFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
TLE2144AMFKB.A	FK	LCCC	20	55	506.98	12.06	2030	NA
TLE2144CDW	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2144CDW.A	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2144CN	N	PDIP	14	25	506	13.97	11230	4.32
TLE2144CN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLE2144IDW	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2144IDW.A	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2144IN	N	PDIP	14	25	506	13.97	11230	4.32
TLE2144IN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLE2144MDW	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2144MDW.A	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2144MDWG4	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2144MDWG4.A	DW	SOIC	16	40	506.98	12.7	4826	6.6
TLE2144MFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
TLE2144MFKB.A	FK	LCCC	20	55	506.98	12.06	2030	NA



4220204/A 02/2017

NOTES:

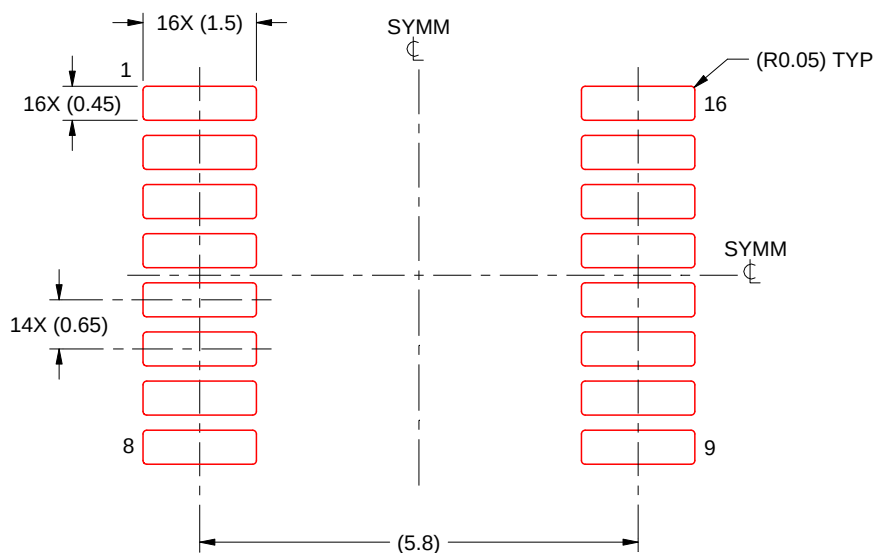
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

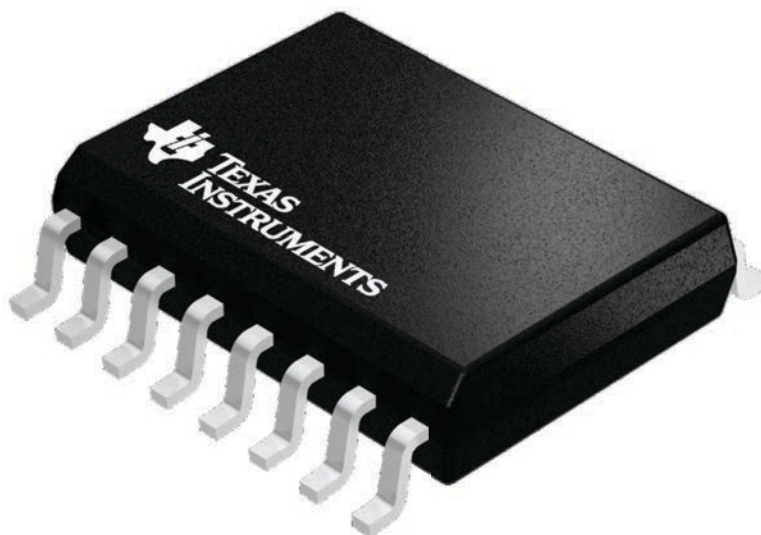
DW 16

SOIC - 2.65 mm max height

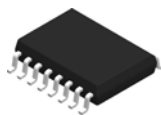
7.5 x 10.3, 1.27 mm pitch

SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4224780/A

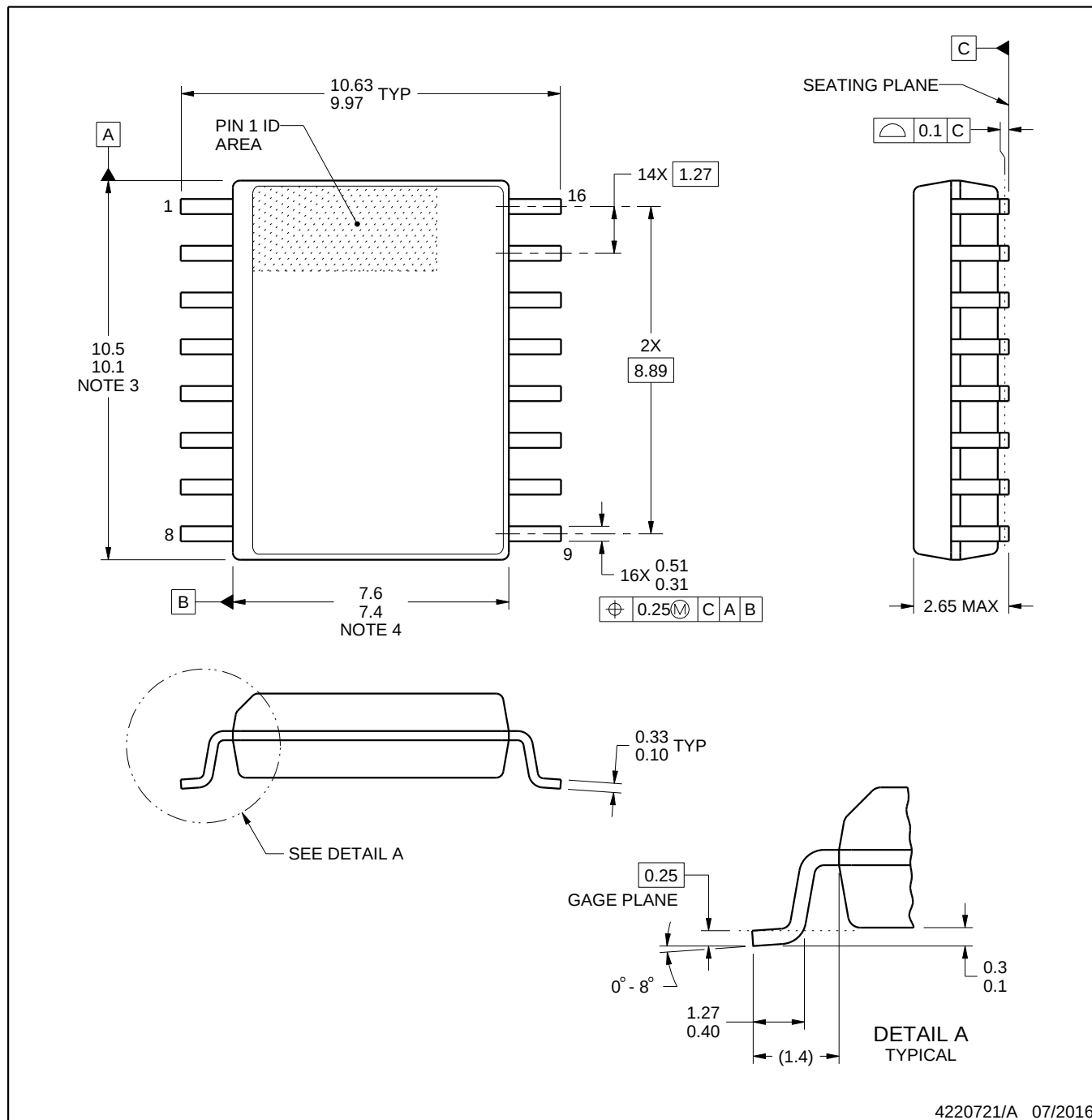


DW0016A

PACKAGE OUTLINE

SOIC - 2.65 mm max height

SOIC



4220721/A 07/2016

NOTES:

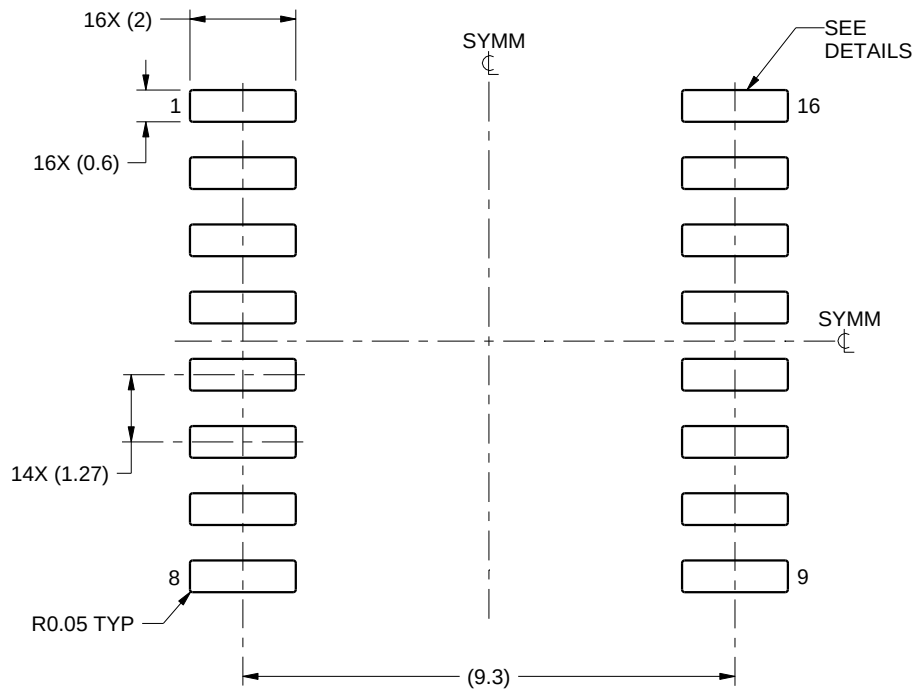
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

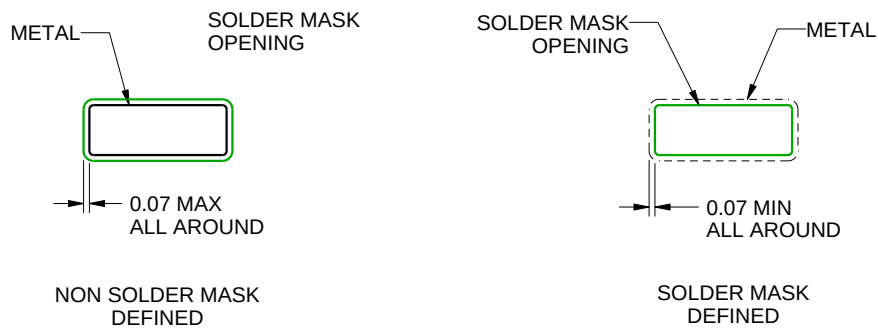
DW0016A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:7X



SOLDER MASK DETAILS

4220721/A 07/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

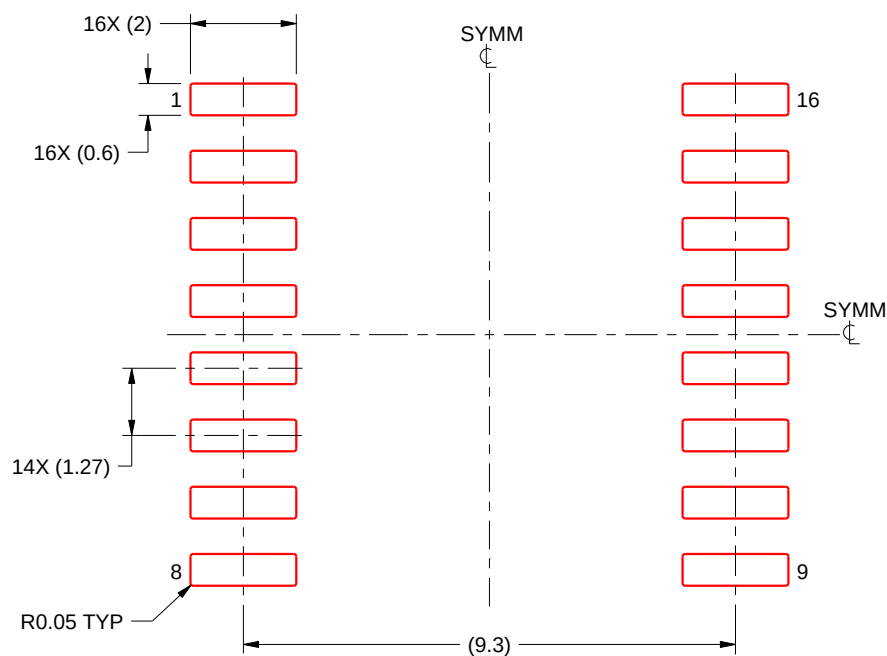
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0016A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

4220721/A 07/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

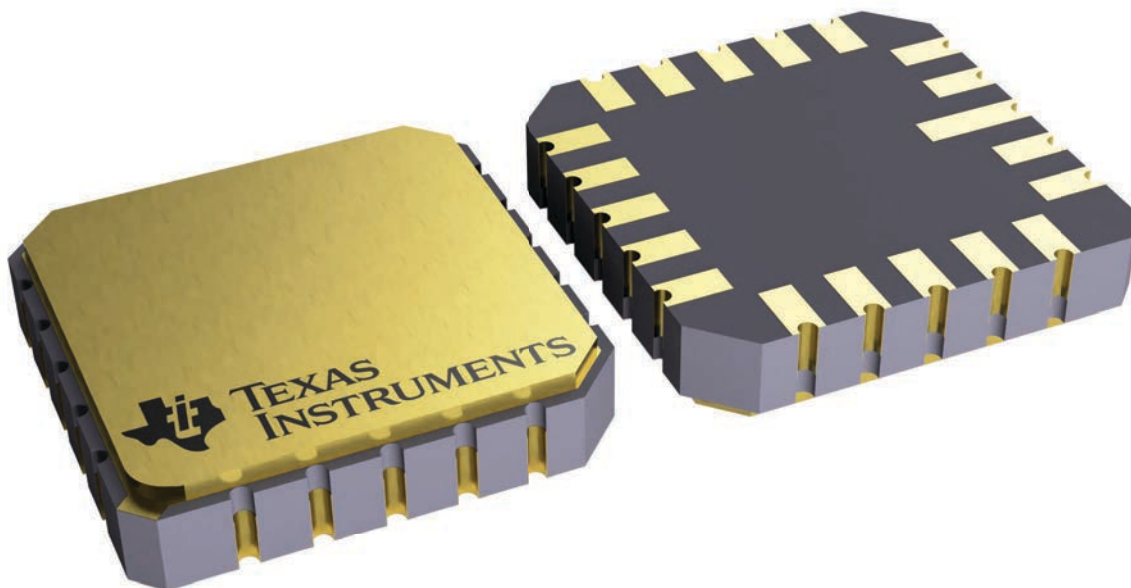
FK 20

LCCC - 2.03 mm max height

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



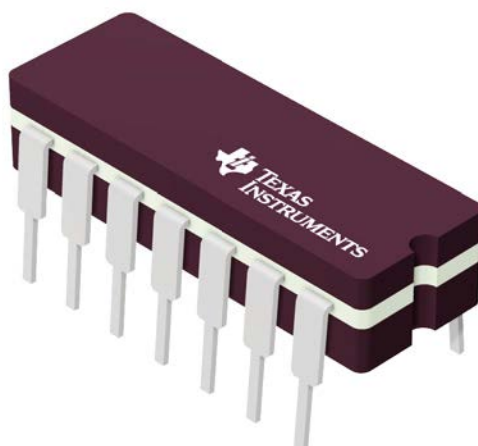
4229370VA\

J 14

GENERIC PACKAGE VIEW

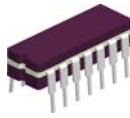
CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE

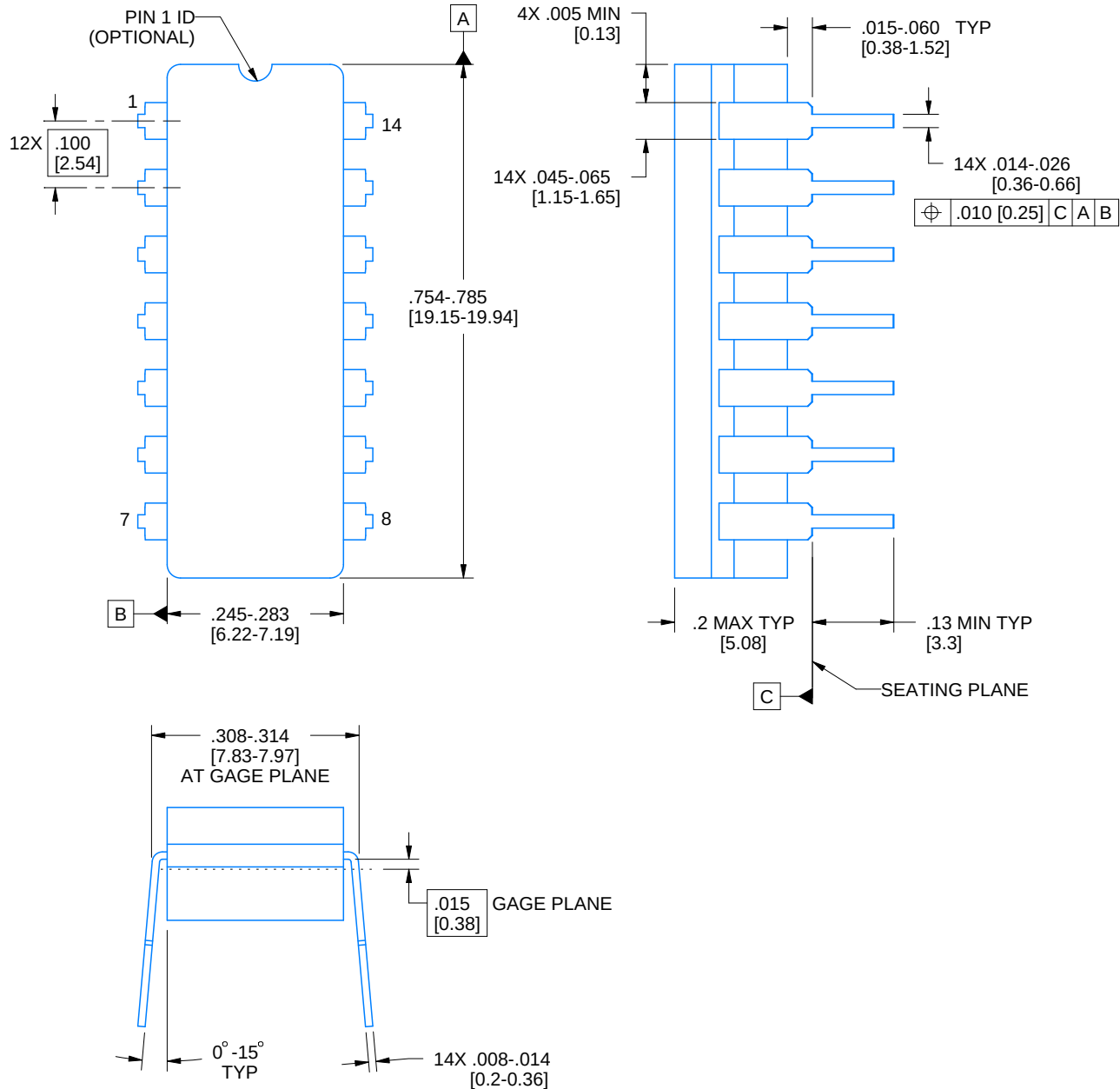


Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4040083-5/G

J0014A**PACKAGE OUTLINE****CDIP - 5.08 mm max height**

CERAMIC DUAL IN LINE PACKAGE



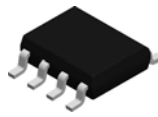
4214771/A 05/2017

NOTES:

1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package is hermetically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
5. Falls within MIL-STD-1835 and GDIP1-T14.



**TEXAS
INSTRUMENTS**
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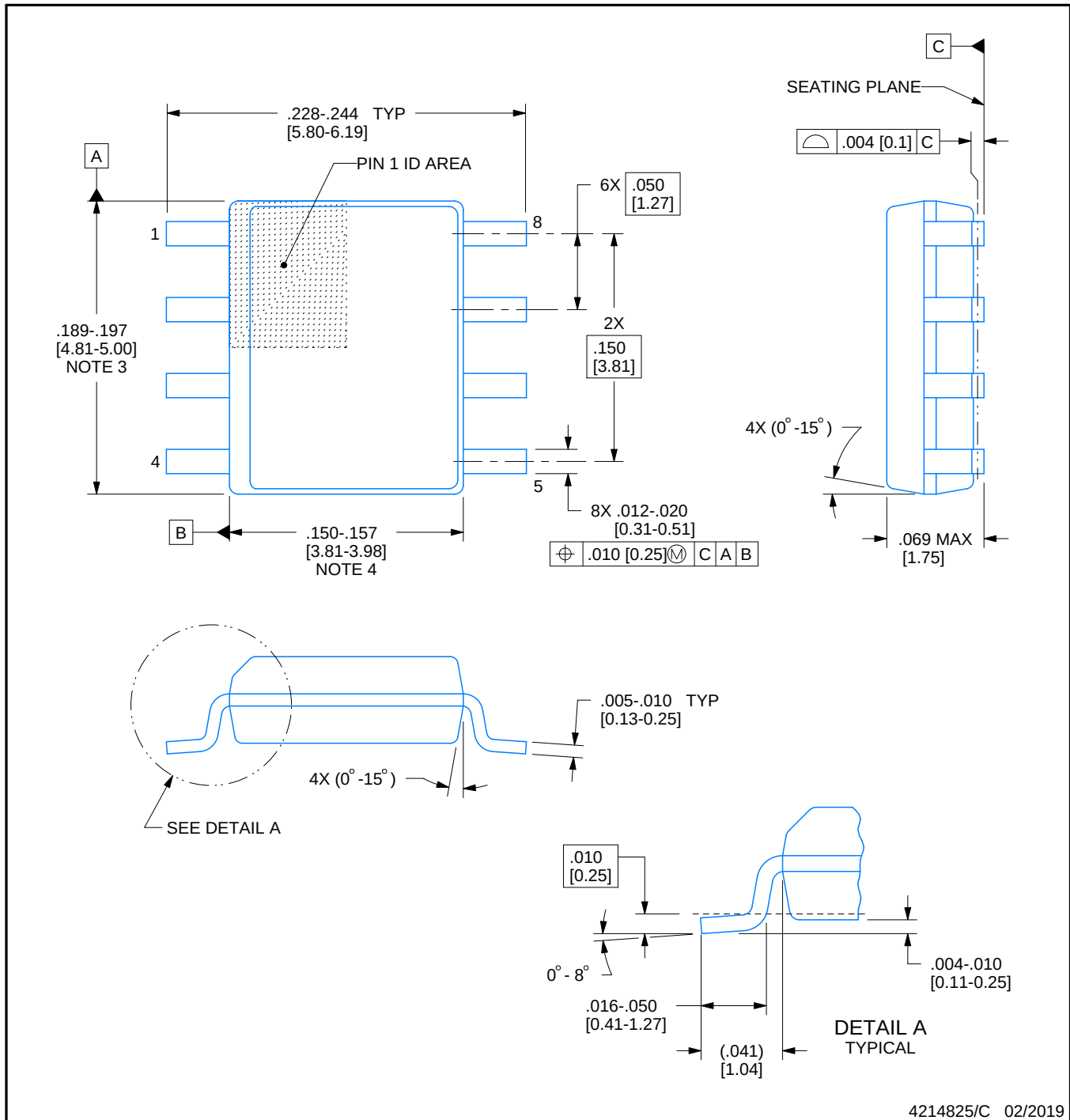


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

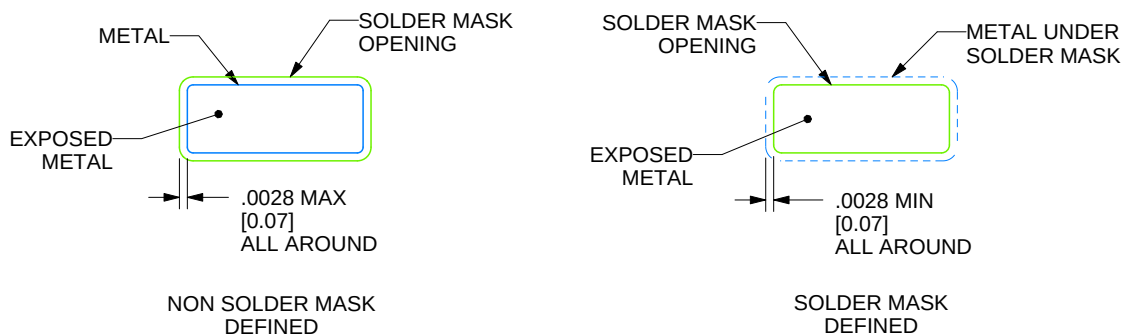
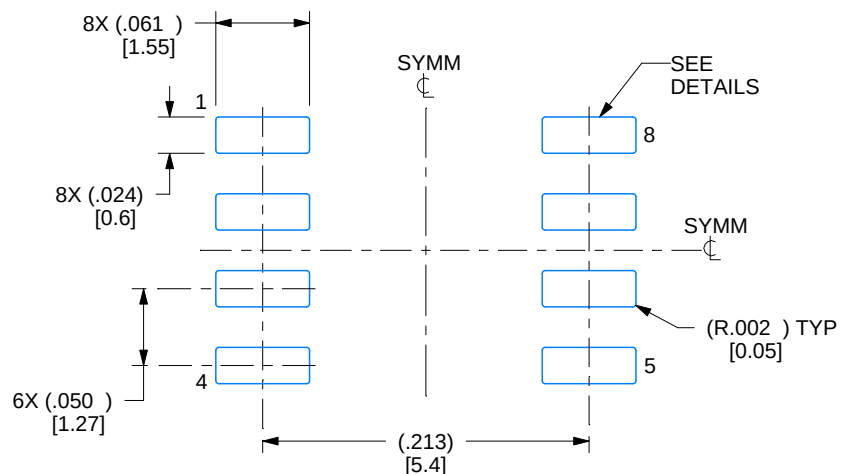
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

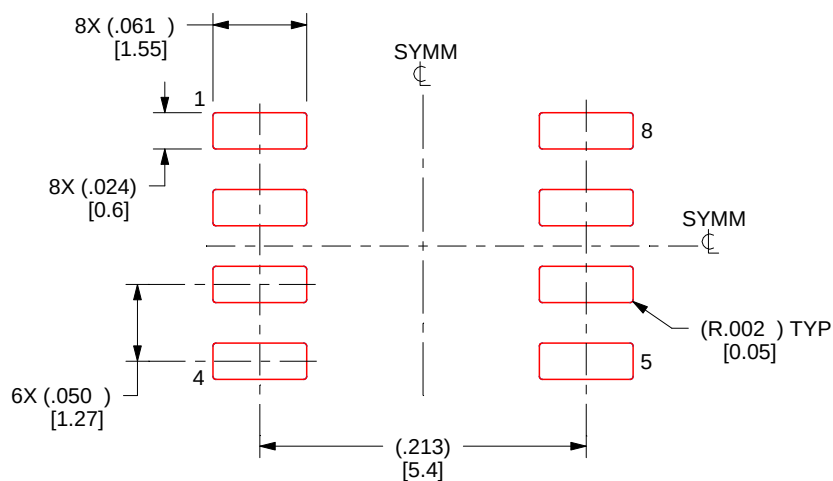
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

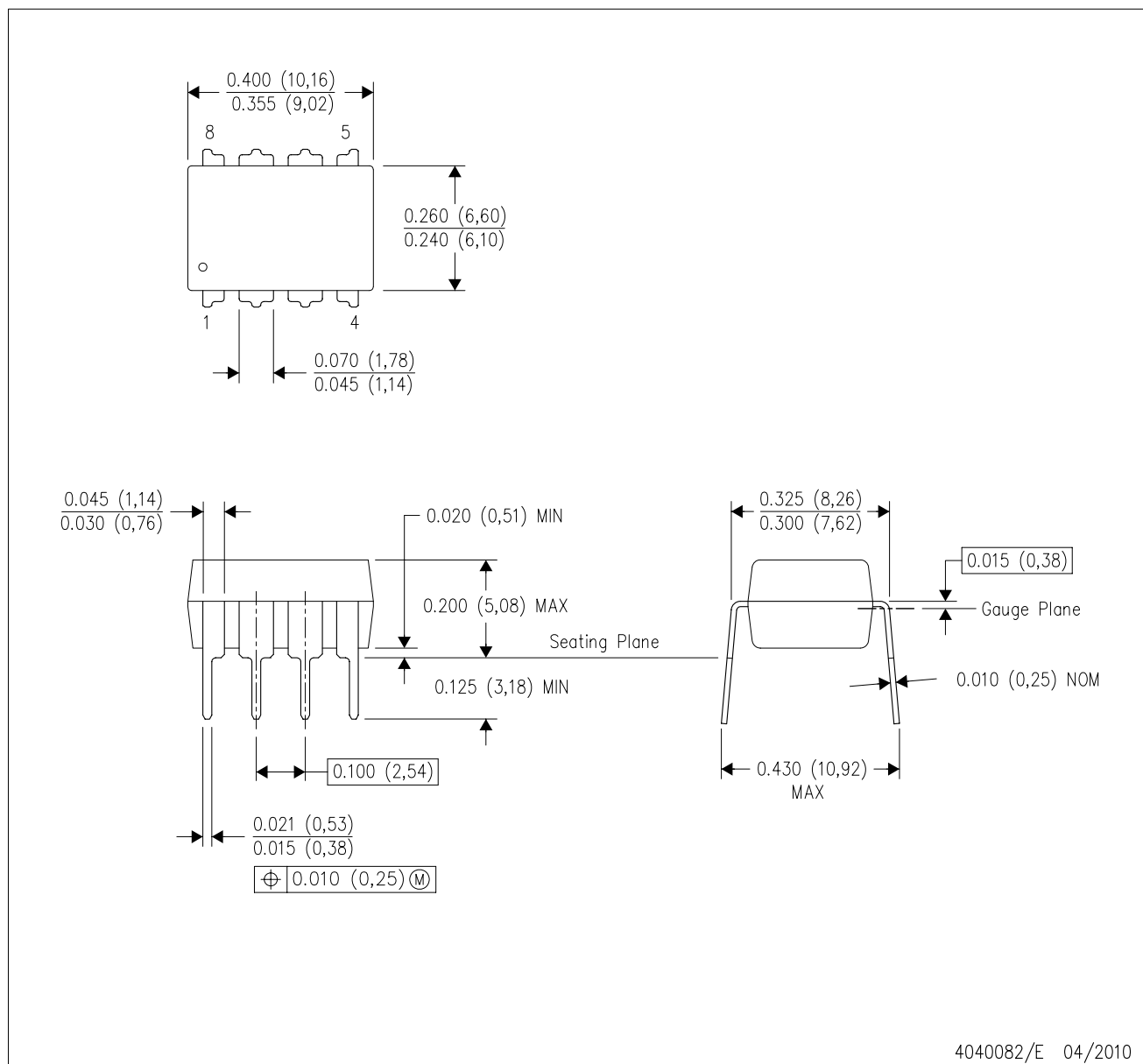
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE

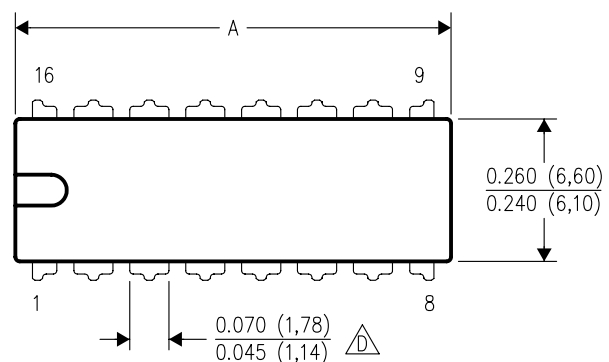


- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

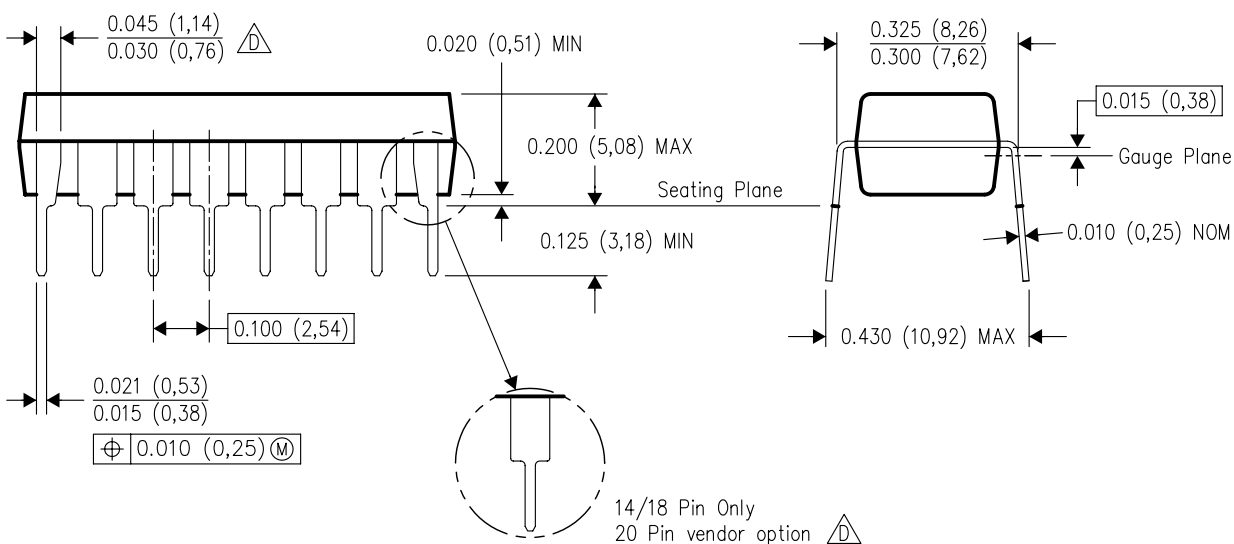
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



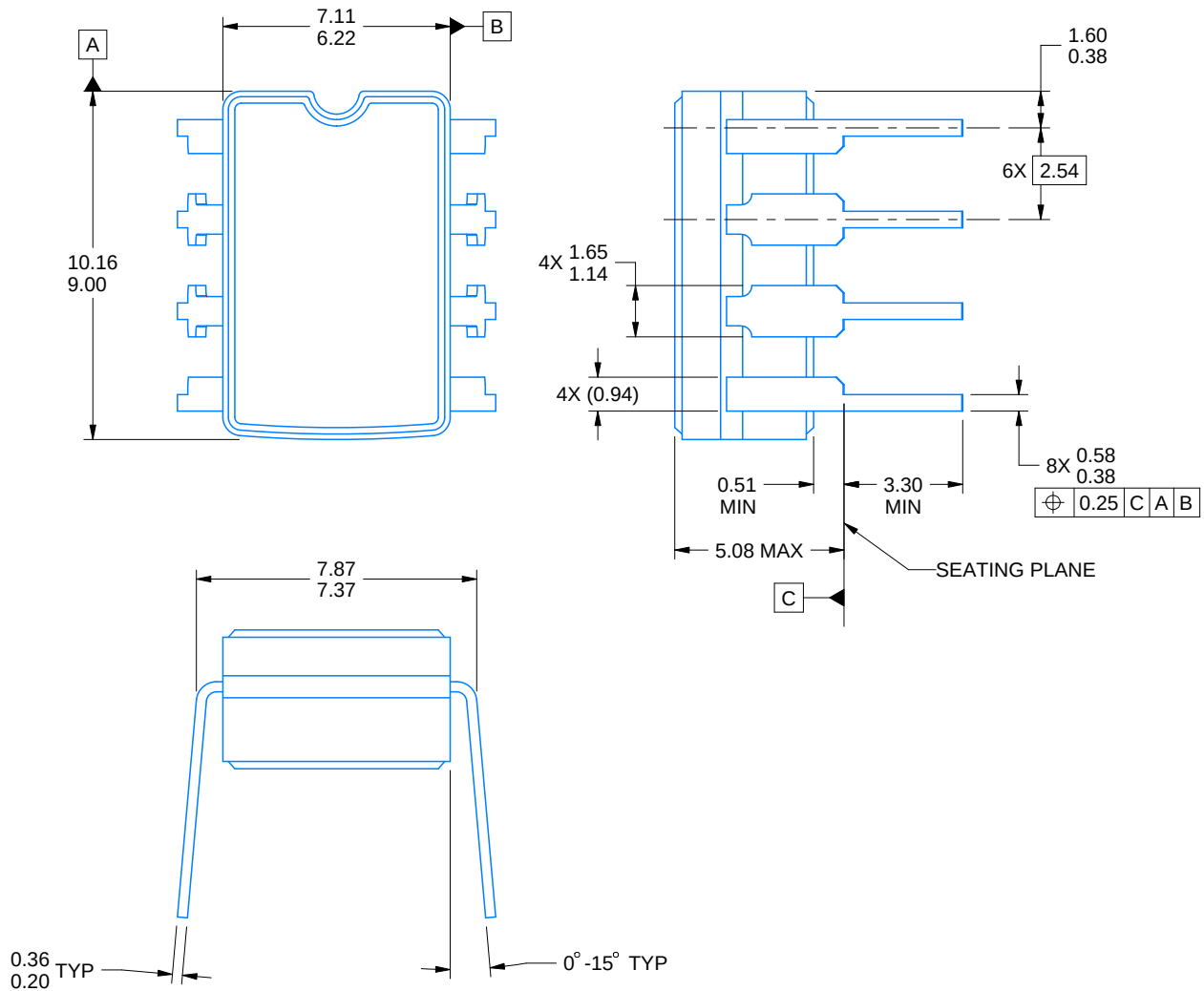
4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.

JG0008A**PACKAGE OUTLINE****CDIP - 5.08 mm max height**

CERAMIC DUAL IN-LINE PACKAGE



4230036/A 09/2023

NOTES:

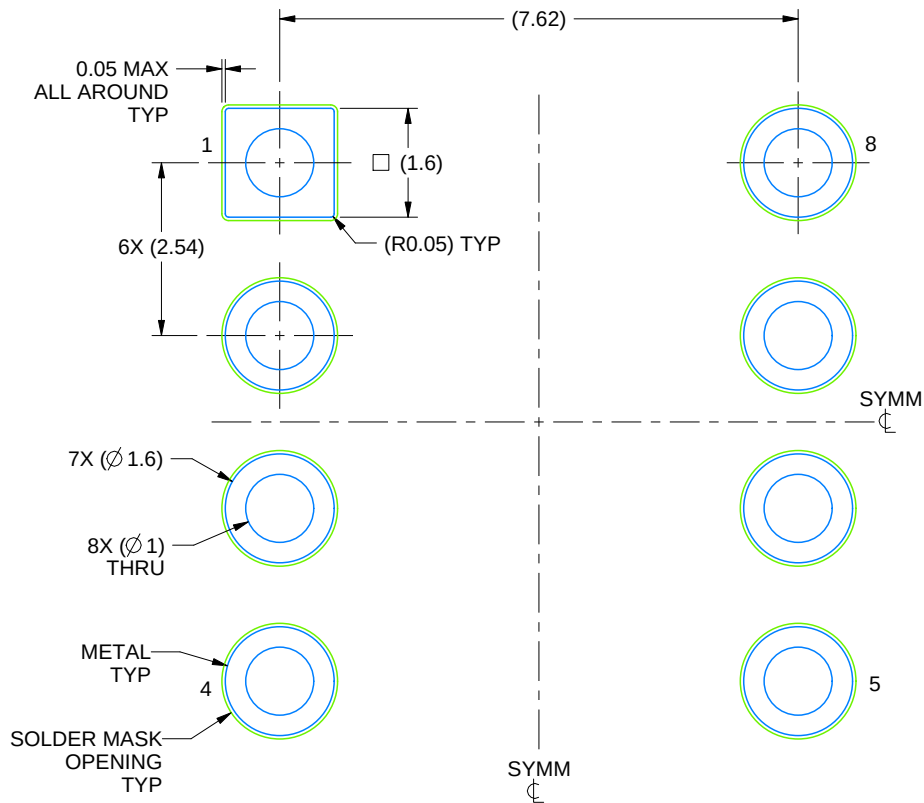
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package can be hermetically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification.
5. Falls within MIL STD 1835 GDIP1-T8

EXAMPLE BOARD LAYOUT

JG0008A

CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE



LAND PATTERN EXAMPLE
NON SOLDER MASK DEFINED
SCALE: 9X

4230036/A 09/2023

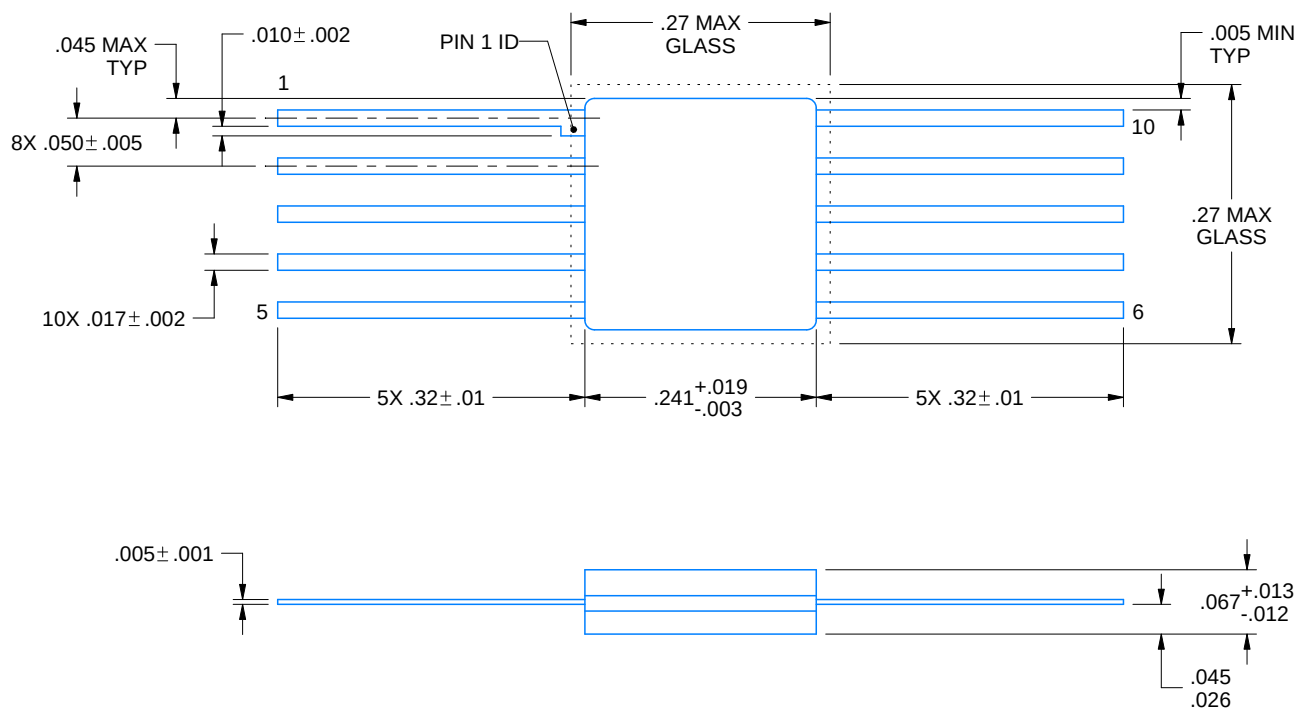
U0010A



PACKAGE OUTLINE

CFP - 2.03 mm max height

CERAMIC FLATPACK



4225582/A 01/2020

NOTES:

1. All linear dimensions are in inches. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

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